MPC860EC Rev. 9, 02/2012

MPC860 PowerQUICC Family **Hardware Specifications**

This hardware specification contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MPC860 family.

To locate published errata or updates for this document, see the MPC860 product summary page on the website listed on the back cover of this document or contact your local Freescale sales office.

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1 Overview

The MPC860 power quad integrated communications controller (PowerQUICCTM) is a versatile one-chip integrated microprocessor and peripheral combination designed for a variety of controller applications. It particularly excels in communications and networking systems. The PowerQUICC unit is referred to as the MPC860 in this hardware specification.

The MPC860 implements Power ArchitectureTM technology and contains a superset of Freescale's MC68360 quad integrated communications controller (QUICC), referred to here as the QUICC, RISC communications proceessor module (CPM). The CPU on the MPC860 is a 32-bit core built on Power Architecture technology that incorporates memory management units (MMUs) and instruction and data caches.. The CPM from the MC68360 QUICC has been enhanced by the addition of the inter-integrated controller (I²C) channel. The memory controller has been enhanced, enabling the MPC860 to support any type of memory, including high-performance memories and new types of DRAMs. A PCMCIA socket controller supports up to two sockets. A real-time clock has also been integrated.

Table 1 shows the functionality supported by the MPC860 family.

	Cache (Kbytes)	Ethe	ernet			
Part	Instruction Cache	Data Cache	10T	10/100	ATM	SCC	Reference ¹
MPC860DE	4	4	Up to 2	_		2	1
MPC860DT	4	4	Up to 2	1	Yes	2	1
MPC860DP	16	8	Up to 2	1	Yes	2	1
MPC860EN	4	4	Up to 4		_	4	1
MPC860SR	4	4	Up to 4	—	Yes	4	1
MPC860T	4	4	Up to 4	1	Yes	4	1
MPC860P	16	8	Up to 4	1	Yes	4	1
MPC855T	4	4	1	1	Yes	1	2

Table 1. MPC860 Family Functionality

Supporting documentation for these devices refers to the following:

1. MPC860 PowerQUICC Family User's Manual (MPC860UM, Rev. 3)

2. MPC855T User's Manual (MPC855TUM, Rev. 1)

The following list summarizes the key MPC860 features:

- Embedded single-issue, 32-bit core (implementing the Power Architecture technology) with thirty-two 32-bit general-purpose registers (GPRs)
 - The core performs branch prediction with conditional prefetch without conditional execution.
 - 4- or 8-Kbyte data cache and 4- or 16-Kbyte instruction cache (see Table 1)
 - 16-Kbyte instruction caches are four-way, set-associative with 256 sets; 4-Kbyte instruction caches are two-way, set-associative with 128 sets.
 - 8-Kbyte data caches are two-way, set-associative with 256 sets; 4-Kbyte data caches are two-way, set-associative with 128 sets.
 - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks.
 - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
 - MMUs with 32-entry TLB, fully-associative instruction, and data TLBs
 - MMUs support multiple page sizes of 4-, 16-, and 512-Kbytes, and 8-Mbytes; 16 virtual address spaces and 16 protection groups
 - Advanced on-chip-emulation debug mode
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- 32 address lines
- Operates at up to 80 MHz
- Memory controller (eight banks)
 - Contains complete dynamic RAM (DRAM) controller
 - Each bank can be a chip select or \overline{RAS} to support a DRAM bank.
 - Up to 15 wait states programmable per memory bank
 - Glueless interface to DRAM, SIMMS, SRAM, EPROM, Flash EPROM, and other memory devices
 - DRAM controller programmable to support most size and speed memory interfaces
 - Four $\overline{\text{CAS}}$ lines, four $\overline{\text{WE}}$ lines, and one $\overline{\text{OE}}$ line
 - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
 - Variable block sizes (32 Kbytes to 256 Mbytes)
 - Selectable write protection
 - On-chip bus arbitration logic
- General-purpose timers
 - Four 16-bit timers or two 32-bit timers
 - Gate mode can enable/disable counting
 - Interrupt can be masked on reference match and event capture.

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- System integration unit (SIU)
 - Bus monitor
 - Software watchdog
 - Periodic interrupt timer (PIT)
 - Low-power stop mode
 - Clock synthesizer
 - Decrementer, time base, and real-time clock (RTC)
 - Reset controller
 - IEEE 1149.1TM Std. test access port (JTAG)
- Interrupts
 - Seven external interrupt request (IRQ) lines
 - 12 port pins with interrupt capability
 - 23 internal interrupt sources
 - Programmable priority between SCCs
 - Programmable highest priority request
- 10/100 Mbps Ethernet support, fully compliant with the IEEE 802.3u® Standard (not available when using ATM over UTOPIA interface)
- ATM support compliant with ATM forum UNI 4.0 specification
 - Cell processing up to 50–70 Mbps at 50-MHz system clock
 - Cell multiplexing/demultiplexing
 - Support of AAL5 and AAL0 protocols on a per-VC basis. AAL0 support enables OAM and software implementation of other protocols.
 - ATM pace control (APC) scheduler, providing direct support for constant bit rate (CBR) and unspecified bit rate (UBR) and providing control mechanisms enabling software support of available bit rate (ABR)
 - Physical interface support for UTOPIA (10/100-Mbps is not supported with this interface) and byte-aligned serial (for example, T1/E1/ADSL)
 - UTOPIA-mode ATM supports level-1 master with cell-level handshake, multi-PHY (up to four physical layer devices), connection to 25-, 51-, or 155-Mbps framers, and UTOPIA/system clock ratios of 1/2 or 1/3.
 - Serial-mode ATM connection supports transmission convergence (TC) function for T1/E1/ADSL lines, cell delineation, cell payload scrambling/descrambling, automatic idle/unassigned cell insertion/stripping, header error control (HEC) generation, checking, and statistics.
- Communications processor module (CPM)
 - RISC communications processor (CP)
 - Communication-specific commands (for example, GRACEFUL STOP TRANSMIT, ENTER HUNT MODE, and RESTART TRANSMIT)
 - Supports continuous mode transmission and reception on all serial channels

- Up to 8 Kbytes of dual-port RAM
- 16 serial DMA (SDMA) channels
- Three parallel I/O registers with open-drain capability
- Four baud-rate generators (BRGs)
 - Independent (can be tied to any SCC or SMC)
 - Allows changes during operation
 - Autobaud support option
- Four serial communications controllers (SCCs)
 - Ethernet/IEEE 802.3[®] standard optional on SCC1–4, supporting full 10-Mbps operation (available only on specially programmed devices)
 - HDLC/SDLC (all channels supported at 2 Mbps)
 - HDLC bus (implements an HDLC-based local area network (LAN))
 - Asynchronous HDLC to support point-to-point protocol (PPP)
 - AppleTalk
 - Universal asynchronous receiver transmitter (UART)
 - Synchronous UART
 - Serial infrared (IrDA)
 - Binary synchronous communication (BISYNC)
 - Totally transparent (bit streams)
 - Totally transparent (frame-based with optional cyclic redundancy check (CRC))
- Two SMCs (serial management channels)
 - UART
 - Transparent
 - General circuit interface (GCI) controller
 - Can be connected to the time-division multiplexed (TDM) channels
- One SPI (serial peripheral interface)
 - Supports master and slave modes
 - Supports multimaster operation on the same bus
- One I²C (inter-integrated circuit) port
 - Supports master and slave modes
 - Multiple-master environment support
- Time-slot assigner (TSA)
 - Allows SCCs and SMCs to run in multiplexed and/or non-multiplexed operation
 - Supports T1, CEPT, PCM highway, ISDN basic rate, ISDN primary rate, user defined
 - 1- or 8-bit resolution
 - Allows independent transmit and receive routing, frame synchronization, and clocking

- Allows dynamic changes
- Can be internally connected to six serial channels (four SCCs and two SMCs)
- Parallel interface port (PIP)
 - Centronics interface support
 - Supports fast connection between compatible ports on the MPC860 or the MC68360
- PCMCIA interface
 - Master (socket) interface, release 2.1 compliant
 - Supports two independent PCMCIA sockets
 - Supports eight memory or I/O windows
- Low power support
 - Full on—all units fully powered
 - Doze—core functional units disabled except time base decrementer, PLL, memory controller, RTC, and CPM in low-power standby
 - Sleep-all units disabled except RTC and PIT, PLL active for fast wake up
 - Deep sleep—all units disabled including PLL except RTC and PIT
 - Power down mode—all units powered down except PLL, RTC, PIT, time base, and decrementer
- Debug interface
 - Eight comparators: four operate on instruction address, two operate on data address, and two
 operate on data
 - Supports conditions: = \neq < >
 - Each watchpoint can generate a break-point internally.
- 3.3-V operation with 5-V TTL compatibility except EXTAL and EXTCLK
- 357-pin ball grid array (BGA) package

3 Maximum Tolerated Ratings

This section provides the maximum tolerated voltage and temperature ranges for the MPC860. Table 2 provides the maximum ratings.

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{DD}).

(GND = 0 V)

Table 2. Maximum Tolerated Ratings

Rating	Symbol	Value	Unit
Supply voltage ¹	V _{DDH}	-0.3 to 4.0	V
	V _{DDL}	-0.3 to 4.0	V
	KAPWR	-0.3 to 4.0	V
	V _{DDSYN}	-0.3 to 4.0	V
Input voltage ²	V _{in}	GND – 0.3 to V _{DDH}	V
Temperature ³ (standard)	T _{A(min)}	0	°C
	T _{j(max)}	95	°C
Temperature ³ (extended)	T _{A(min)}	-40	°C
	T _{j(max)}	95	°C
Storage temperature range	T _{stg}	–55 to 150	°C

¹ The power supply of the device must start its ramp from 0.0 V.

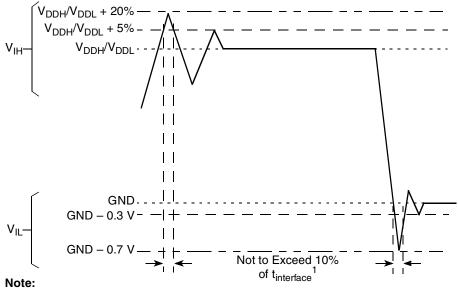
² Functional operating conditions are provided with the DC electrical specifications in Table 6. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device.

Caution: All inputs that tolerate 5 V cannot be more than 2.5 V greater than the supply voltage. This restriction applies to power-up and normal operation (that is, if the MPC860 is unpowered, voltage greater than 2.5 V must not be applied to its inputs).

³ Minimum temperatures are guaranteed as ambient temperature, T_A. Maximum temperatures are guaranteed as junction temperature, T_j.

Thermal Characteristics

Figure 1 shows the undershoot and overshoot voltages at the interface of the MPC860.



1. t_{interface} refers to the clock period associated with the bus clock interface.



4 Thermal Characteristics

Table 3. Package Description

Package Designator	Package Code (Case No.)	Package Description
ZP	5050 (1103-01)	PBGA 357 25*25*0.9P1.27
ZQ/VR	5058 (1103D-02)	PBGA 357 25*25*1.2P1.27

Table 4 shows the thermal characteristics for the MPC860.

Rating	Env	rironment	Symbol	ZP MPC860P	ZQ / VR MPC860P	Unit
Mold Compound Thicknes	Mold Compound Thickness					mm
Junction-to-ambient ¹	Natural convection	Single-layer board (1s)	$R_{\theta JA}^2$	34	34	•C/W
		Four-layer board (2s2p)	$R_{\theta JMA}^{3}$	22	22	
	Airflow (200 ft/min)	Single-layer board (1s)	$R_{\theta JMA}^{3}$	27	27	
		Four-layer board (2s2p)	$R_{\theta JMA}^{3}$	18	18	
Junction-to-board ⁴			$R_{\theta JB}$	14	13	
Junction-to-case ⁵			R _{θJC}	6	8	
Junction-to-package top ⁶	Natural convection		Ψ _{JT}	2	2	

Table 4. MPC860 Thermal Resistance Data

¹ Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.

² Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal.

³ Per JEDEC JESD51-6 with the board horizontal.

⁴ Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

- ⁵ Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature. For exposed pad packages where the pad would be expected to be soldered, junction-to-case thermal resistance is a simulated value from the junction to the exposed pad without contact resistance.
- ⁶ Thermal characterization parameter indicating the temperature difference between the package top and the junction temperature per JEDEC JESD51-2.

5 **Power Dissipation**

Table 5 provides power dissipation information. The modes are 1:1, where CPU and bus speeds are equal, and 2:1, where CPU frequency is twice the bus speed.

Die Revision	Frequency (MHz)	Typical ¹	Maximum ²	Unit
D.4	50	656	735	mW
(1:1 mode)	66	TBD	TBD	mW
D.4	66	722	762	mW
(2:1 mode)	80	851	909	mW

Table 5. Power Dissipation (PD)

¹ Typical power dissipation is measured at 3.3 V.

² Maximum power dissipation is measured at 3.5 V.

NOTE

Values in Table 5 represent V_{DDL} -based power dissipation and do not include I/O power dissipation over V_{DDH} . I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

6 DC Characteristics

Table 6 provides the DC electrical characteristics for the MPC860.

 Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Мах	Unit
Operating voltage at 40 MHz or less	V _{DDH} , V _{DDL} , V _{DDSYN}	3.0	3.6	V
	KAPWR (power-down mode)	2.0	3.6	V
	KAPWR (all other operating modes)	V _{DDH} – 0.4	V _{DDH}	V
Operating voltage greater than 40 MHz	V _{DDH} , V _{DDL} , KAPWR, V _{DDSYN}	3.135	3.465	V
	KAPWR (power-down mode)	2.0	3.6	V
	KAPWR (all other operating modes)	V _{DDH} – 0.4	V _{DDH}	V
Input high voltage (all inputs except EXTAL and EXTCLK)	V _{IH}	2.0	5.5	V
Input low voltage ¹	V _{IL}	GND	0.8	V
EXTAL, EXTCLK input high voltage	V _{IHC}	$0.7 imes (V_{DDH})$	V _{DDH} + 0.3	V
Input leakage current, $V_{in} = 5.5 \text{ V}$ (except TMS, TRST, DSCK, and DSDI pins)	l _{in}	_	100	μA

Characteristic	Symbol	Min	Мах	Unit
Input leakage current, $V_{in} = 3.6 \text{ V}$ (except TMS, TRST, DSCK, and DSDI pins)	l _{in}	_	10	μΑ
Input leakage current, V _{in} = 0 V (except TMS, TRST, DSCK, and DSDI pins)	l _{in}	—	10	μA
Input capacitance ²	C _{in}	—	20	pF
Output high voltage, $I_{OH} = -2.0 \text{ mA}$, $V_{DDH} = 3.0 \text{ V}$ (except XTAL, XFC, and open-drain pins)	V _{OH}	2.4	—	V
Output low voltage $I_{OL} = 2.0 \text{ mA}, \text{CLKOUT}$ $I_{OL} = 3.2 \text{ mA}^3$ $I_{OL} = 5.3 \text{ mA}^4$ $I_{OL} = 7.0 \text{ mA}, \underline{\text{TXD1/PA14}}, \underline{\text{TXD2/PA12}}$ $I_{OL} = 8.9 \text{ mA}, \overline{\text{TS}}, \overline{\text{TA}}, \overline{\text{TEA}}, \overline{\text{BI}}, \overline{\text{BB}}, \overline{\text{HRESET}}, \overline{\text{SRESET}}$	V _{OL}	_	0.5	V

Table 6. DC Electrical Specifications (continued)

¹ V_{II} (max) for the I²C interface is 0.8 V rather than the 1.5 V as specified in the I²C standard.

² Input capacitance is periodically sampled.

- ³ A(0:31), TSIZ0/REG, TSIZ1, D(0:31), DP(0:3)/IRQ(3:6), RD/WR, BURST, RSV/IRQ2, IP_B(0:1)/IWP(0:1)/VFLS(0:1), IP_B2/IOIS16_B/AT2, IP_B3/IWP2/VF2, IP_B4/LWP0/VF0, IP_B5/LWP1/VF1, IP_B6/DSDI/AT0, IP_B7/PTR/AT3, RXD1/PA15, RXD2/PA13, L1TXDB/PA11, L1RXDB/PA10, L1TXDA/PA9, L1RXDA/PA8, TIN1/L1RCLKA/BRGO1/CLK1/PA7, BRGCLK1/TOUT1/CLK2/PA6, TIN2/L1TCLKA/BRGO2/CLK3/PA5, TOUT2/CLK4/PA4, TIN3/BRGO3/CLK5/PA3, BRGCLK2/ L1RCLKB/TOUT3/CLK6/PA2, TIN4/BRGO4/CLK7/PA1, L1TCLKB/TOUT4/CLK8/PA0, REJCT1/SPISEL/PB31, SPICLK/ PB30,SPIMOSI/PB29, BRGO4/SPIMISO/PB28, BRGO1/I2CSDA/PB27, BRGO2/I2CSCL/PB26, SMTXD1/PB25, SMRXD1/ PB24, SMSYN1/SDACK1/PB23, SMSYN2/SDACK2/PB22, SMTXD2/L1CLKOB/PB21, SMRXD2/L1CLKOA/PB20, L1ST1/ RTS1/PB19, L1ST2/RTS2/PB18, L1ST3/L1RQB/PB17, L1ST4/L1RQA/PB16, BRGO3/PB15, RSTRT1/PB14, L1ST1/RTS1/ DREQ0/PC15, L1ST2/RTS2/DREQ1/PC14, L1ST3/L1RQB/PC13, L1ST4/L1RQA/PC12, CTS1/PC11, TGATE1/CD1/PC10, CTS2/PC9, TGATE2/CD2/PC8, SDACK2/L1TSYNCB/PC7, L1RSYNCB/PC6, SDACK1/L1TSYNCA/PC5, L1RSYNCA/PC4, PD15, PD14, PD13, PD12, PD11, PD10, PD9, PD8, PD5, PD6, PD7, PD4, PD3, MII_MDC, MII_TX_ER, MII_EN, MII_MDIO, and MII_TXD[0:3]
- ⁴ BDIP/GPL_B(5), BR, BG, FRZ/IRQ6, CS(0:5), CS(6)/CE(1)_B, CS(7)/CE(2)_B, WE0/BS_B0/IORD, WE1/BS_B1/IOWR, WE2/BS_B2/PCOE, WE3/BS_B3/PCWE, BS_A(0:3), GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A(2:3)/GPL_B(2:3)/ CS(2:3), UPWAITA/GPL_A4, UPWAITB/GPL_B4, GPL_A5, ALE_A, CE1_A, CE2_A, ALE_B/DSCK/AT1, OP(0:1), OP2/MODCK1/STS, OP3/MODCK2/DSDO, and BADDR(28:30)

Thermal Calculation and Measurement

7 Thermal Calculation and Measurement

For the following discussions, $P_D = (V_{DD} \times I_{DD}) + PI/O$, where PI/O is the power dissipation of the I/O drivers.

7.1 Estimation with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_J, in °C can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

 T_A = ambient temperature (°C)

 $R_{\theta JA}$ = package junction-to-ambient thermal resistance (°C/W)

 P_D = power dissipation in package

The junction-to-ambient thermal resistance is an industry standard value which provides a quick and easy estimation of thermal performance. However, the answer is only an estimate; test cases have demonstrated that errors of a factor of two (in the quantity $T_I - T_A$) are possible.

7.2 Estimation with Junction-to-Case Thermal Resistance

Historically, the thermal resistance has frequently been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

 $R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$

where:

 $R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

 $R_{\theta IC}$ = junction-to-case thermal resistance (°C/W)

 $R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$ is device related and cannot be influenced by the user. The user adjusts the thermal environment to affect the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the airflow around the device, add a heat sink, change the mounting arrangement on the printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device. This thermal model is most useful for ceramic packages with heat sinks where some 90% of the heat flows through the case and the heat sink to the ambient environment. For most packages, a better model is required.

7.3 Estimation with Junction-to-Board Thermal Resistance

A simple package thermal model which has demonstrated reasonable accuracy (about 20%) is a two-resistor model consisting of a junction-to-board and a junction-to-case thermal resistance. The junction-to-case thermal resistance covers the situation where a heat sink is used or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed-circuit board. It has been observed that the thermal performance of most plastic packages, especially PBGA packages, is strongly dependent on the board temperature; see Figure 2.

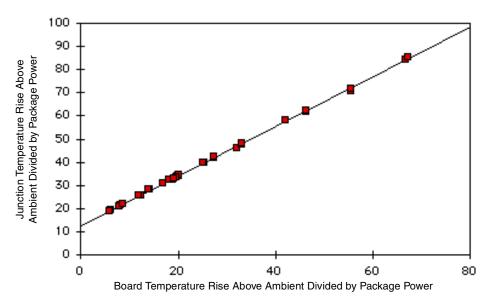


Figure 2. Effect of Board Temperature Rise on Thermal Behavior

If the board temperature is known, an estimate of the junction temperature in the environment can be made using the following equation:

$$T_{J} = T_{B} + (R_{\theta JB} \times P_{D})$$

where:

 $R_{\theta JB}$ = junction-to-board thermal resistance (°C/W)

 $T_B = \text{board temperature (°C)}$

 P_D = power dissipation in package

If the board temperature is known and the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. For this method to work, the board and board mounting must be similar to the test board used to determine the junction-to-board thermal resistance, namely a 2s2p (board with a power and a ground plane) and by attaching the thermal balls to the ground plane.

7.4 Estimation Using Simulation

When the board temperature is not known, a thermal simulation of the application is needed. The simple two-resistor model can be used with the thermal simulation of the application [2], or a more accurate and complex model of the package can be used in the thermal simulation.

7.5 Experimental Determination

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

Layout Practices

where:

 Ψ_{JT} = thermal characterization parameter

 T_T = thermocouple temperature on top of package

 P_D = power dissipation in package

The thermal characterization parameter is measured per JEDEC JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

7.6 References

Semiconductor Equipment and Materials International	(415) 964-5111
805 East Middlefield Rd.	
Mountain View, CA 94043	
MIL-SPEC and EIA/JESD (JEDEC) Specifications	800-854-7179 or
(Available from Global Engineering Documents)	303-397-7956
JEDEC Specifications	http://www.jedec.org

- 1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
- 2. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

8 Layout Practices

Each V_{DD} pin on the MPC860 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on the chip. The V_{DD} power supply should be bypassed to ground using at least four 0.1 µF-bypass capacitors located as close as possible to the four sides of the package. The capacitor leads and associated printed circuit traces connecting to chip V_{DD} and GND should be kept to less than half an inch per capacitor lead. A four-layer board employing two inner layers as V_{CC} and GND planes is recommended.

All output pins on the MPC860 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of 6 inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{CC} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins.

Table 7 provides the bus operation timing for the MPC860 at 33, 40, 50, and 66 MHz.

The maximum bus speed supported by the MPC860 is 66 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC860 used at 80 MHz must be configured for a 40-MHz bus).

The timing for the MPC860 bus shown assumes a 50-pF load for maximum delays and a 0-pF load for minimum delays.

		33	MHz	40 I	MHz	50 I	MHz	66 I	MHz	
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B1	CLKOUT period	30.30	30.30	25.00	30.30	20.00	30.30	15.15	30.30	ns
B1a	EXTCLK to CLKOUT phase skew (EXTCLK > 15 MHz and MF <= 2)	-0.90	0.90	-0.90	0.90	-0.90	0.90	-0.90	0.90	ns
B1b	EXTCLK to CLKOUT phase skew (EXTCLK > 10 MHz and MF < 10)	-2.30	2.30	-2.30	2.30	-2.30	2.30	-2.30	2.30	ns
B1c	CLKOUT phase jitter (EXTCLK > 15 MHz and MF <= 2) ¹	-0.60	0.60	-0.60	0.60	-0.60	0.60	-0.60	0.60	ns
B1d	CLKOUT phase jitter ¹	-2.00	2.00	-2.00	2.00	-2.00	2.00	-2.00	2.00	ns
B1e	CLKOUT frequency jitter (MF < 10) ¹	_	0.50	_	0.50	_	0.50	_	0.50	%
B1f	CLKOUT frequency jitter (10 < MF < 500) ¹	_	2.00	_	2.00	_	2.00	_	2.00	%
B1g	CLKOUT frequency jitter (MF > 500) ¹	_	3.00	_	3.00	_	3.00	_	3.00	%
B1h	Frequency jitter on EXTCLK ²	_	0.50	_	0.50	_	0.50	_	0.50	%
B2	CLKOUT pulse width low	12.12	_	10.00	_	8.00	_	6.06		ns
B3	CLKOUT width high	12.12	_	10.00	_	8.00	_	6.06	_	ns
B4	CLKOUT rise time ³	_	4.00		4.00		4.00	_	4.00	ns
B5 ³³	CLKOUT fall time ³	_	4.00	_	4.00	_	4.00	_	4.00	ns
B7	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), DP(0:3) invalid	7.58	—	6.25	—	5.00	—	3.80	—	ns
B7a	CLKOUT to TSIZ(0:1), REG, RSV, AT(0:3), BDIP, PTR invalid	7.58	—	6.25	—	5.00	—	3.80	_	ns
B7b	CLKOUT to BR, BG, FRZ, VFLS(0:1), VF(0:2) IWP(0:2), LWP(0:1), STS invalid ⁴	7.58	—	6.25	—	5.00	—	3.80	_	ns
B8	CLKOUT to A(0:31), BADDR(28:30) RD/WR, BURST, D(0:31), DP(0:3) valid	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B8a	CLKOUT to TSIZ(0:1), REG, RSV, AT(0:3) BDIP, PTR valid	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B8b	CLKOUT to BR, BG, VFLS(0:1), VF(0:2), IWP(0:2), FRZ, LWP(0:1), STS valid ⁴	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns

 Table 7. Bus Operation Timings

		33 I	MHz	40 I	MHz	50 I	MHz 66 MHz			
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B9	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), DP(0:3), TSIZ(0:1), REG, RSV, AT(0:3), PTR High-Z	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B11	CLKOUT to TS, BB assertion	7.58	13.58	6.25	12.25	5.00	11.00	3.80	11.29	ns
B11a	CLKOUT to \overline{TA} , \overline{BI} assertion (when driven by the memory controller or PCMCIA interface)	2.50	9.25	2.50	9.25	2.50	9.25	2.50	9.75	ns
B12	CLKOUT to \overline{TS} , \overline{BB} negation	7.58	14.33	6.25	13.00	5.00	11.75	3.80	8.54	ns
B12a	CLKOUT to \overline{TA} , \overline{BI} negation (when driven by the memory controller or PCMCIA interface)	2.50	11.00	2.50	11.00	2.50	11.00	2.50	9.00	ns
B13	CLKOUT to TS, BB High-Z	7.58	21.58	6.25	20.25	5.00	19.00	3.80	14.04	ns
B13a	CLKOUT to \overline{TA} , \overline{BI} High-Z (when driven by the memory controller or PCMCIA interface)	2.50	15.00	2.50	15.00	2.50	15.00	2.50	15.00	ns
B14	CLKOUT to TEA assertion	2.50	10.00	2.50	10.00	2.50	10.00	2.50	9.00	ns
B15	CLKOUT to TEA High-Z	2.50	15.00	2.50	15.00	2.50	15.00	2.50	15.00	ns
B16	TA, BI valid to CLKOUT (setup time)	9.75	_	9.75	_	9.75	_	6.00	—	ns
B16a	TEA, KR, RETRY, CR valid to CLKOUT (setup time)	10.00	—	10.00	—	10.00		4.50	—	ns
B16b	$\overline{\text{BB}}, \overline{\text{BG}}, \overline{\text{BR}}, \text{ valid to CLKOUT (setup time)}^5$	8.50		8.50		8.50	_	4.00	_	ns
B17	CLKOUT to TA, TEA, BI, BB, BG, BR valid (hold time)	1.00	—	1.00	—	1.00	_	2.00	—	ns
B17a	CLKOUT to \overline{KR} , \overline{RETRY} , \overline{CR} valid (hold time)	2.00	—	2.00	_	2.00		2.00	_	ns
B18	D(0:31), DP(0:3) valid to CLKOUT rising edge (setup time) ⁶	6.00	_	6.00	_	6.00		6.00	_	ns
B19	CLKOUT rising edge to D(0:31), DP(0:3) valid (hold time) ⁶	1.00	—	1.00	_	1.00		2.00	_	ns
B20	D(0:31), DP(0:3) valid to CLKOUT falling edge (setup time) ⁷	4.00	_	4.00	_	4.00		4.00	_	ns
B21	CLKOUT falling edge to D(0:31), DP(0:3) valid (hold time) ⁷	2.00	—	2.00	_	2.00		2.00	-	ns
B22	CLKOUT rising edge to \overline{CS} asserted GPCM ACS = 00	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B22a	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 10, TRLX = 0		8.00	_	8.00	_	8.00	_	8.00	ns
B22b	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B22c	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 1	10.86	17.99	8.88	16.00	7.00	14.13	5.18	12.31	ns

Table 7. Bus Operation Timings (continued)
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Num	Choracteristic	33 MHz		40 MHz		50 MHz		66 MHz		11
Num	Characteristic	Min	Max	Min	Max	Min	Мах	Min	Мах	Unit
B23	CLKOUT rising edge to \overline{CS} negated GPCM read access, GPCM write access ACS = 00, TRLX = 0, and CSNT = 0	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns
B24	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 0	5.58	_	4.25	—	3.00	—	1.79	—	ns
B24a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 0	13.15		10.50	—	8.00	—	5.58	—	ns
B25	CLKOUT rising edge to \overline{OE} , \overline{WE} (0:3) asserted	—	9.00	—	9.00	—	9.00	—	9.00	ns
B26	CLKOUT rising edge to OE negated	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 1	35.88	_	29.25	—	23.00	—	16.94	—	ns
B27a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 1	43.45	_	35.50	—	28.00	—	20.73	—	ns
B28	CLKOUT rising edge to $\overline{WE}(0:3)$ negated GPCM write access CSNT = 0	_	9.00	_	9.00	_	9.00	_	9.00	ns
B28a	CLKOUT falling edge to $\overline{WE}(0:3)$ negated GPCM write access TRLX = 0, 1, CSNT = 1, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B28b	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 0		14.33		13.00		11.75	—	10.54	ns
B28c	CLKOUT falling edge to \overline{WE} (0:3) negated GPCM write access TRLX = 0, 1, CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	10.86	17.99	8.88	16.00	7.00	14.13	5.18	12.31	ns
B28d	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1	_	17.99	_	16.00	_	14.13	_	12.31	ns
B29	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access CSNT = 0, EBDF = 0	5.58	_	4.25	_	3.00	_	1.79	—	ns
B29a	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, EBDF = 0	13.15		10.5	_	8.00	_	5.58	_	ns
B29b	\overline{CS} negated to D(0:31), DP(0:3), High-Z GPCM write access, ACS = 00, TRLX = 0, 1, and CSNT = 0	5.58		4.25		3.00		1.79		ns
B29c	\overline{CS} negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 0	13.15		10.5		8.00		5.58		ns

NI	Ob an a data in the	33 MHz		40	40 MHz		MHz	66 MHz		<u></u>
Num	Characteristic	Min	Max	Min	Max	Min	Мах	Min	Max	Unit
B29d	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	43.45		35.5		28.00		20.73		ns
B29e	$\overline{\text{CS}}$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 0	43.45		35.5	_	28.00	—	29.73	—	ns
B29f	\overline{WE} (0:3) negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, EBDF = 1	8.86		6.88	_	5.00	_	3.18	_	ns
B29g	$\overline{\text{CS}}$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1	8.86		6.88	_	5.00	_	3.18	—	ns
B29h	$\overline{WE}(0:3)$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 1	38.67	_	31.38	_	24.50	—	17.83	—	ns
B29i	$\overline{\text{CS}}$ negated to D(0:31), DP(0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1	38.67		31.38		24.50		17.83	—	ns
B30	CS, WE(0:3) negated to A(0:31), BADDR(28:30) invalid GPCM write access ⁸	5.58		4.25	—	3.00	—	1.79	—	ns
B30a	\overline{WE} (0:3) negated to A(0:31), BADDR(28:30) invalid GPCM, write access, TRLX = 0, CSNT = 1, \overline{CS} negated to A(0:31) invalid GPCM write access, TRLX = 0, CSNT = 1 ACS = 10, or ACS = 11, EBDF = 0	13.15	_	10.50	_	8.00	_	5.58	_	ns
B30b	$\label{eq:weighted} \hline \hline WE(0:3) \ negated to \ A(0:31), \ invalid \ GPCM \\ BADDR(28:30) \ invalid \ GPCM \ write \ access, \\ TRLX = 1, \ CSNT = 1. \ \overline{CS} \ negated to \\ A(0:31), \ Invalid \ GPCM, \ write \ access, \\ TRLX = 1, \ CSNT = 1, \ ACS = 10, \ or \\ ACS = 11, \ EBDF = 0 \\ \hline \hline \hline \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	43.45		35.50	_	28.00	_	20.73	_	ns
B30c	$\label{eq:weighted} \begin{array}{ c c c c c } \hline \hline WE(0:3) \mbox{ negated to } A(0:31), \mbox{ BADDR}(28:30) \\ \hline invalid \mbox{ GPCM write access, TRLX = 0, } \\ \hline CSNT = 1. \end{cmathcelline CS} \mbox{ negated to } A(0:31) \mbox{ invalid } \\ \hline GPCM \mbox{ write access, TRLX = 0, } \\ \hline CSNT = 10, \mbox{ ACS = 11, EBDF = 1} \end{array}$	8.36	_	6.38	_	4.50	_	2.68	_	ns
B30d	$\overline{WE}(0:3)$ negated to A(0:31), BADDR(28:30) invalid GPCM write access, TRLX = 1, CSNT =1. \overline{CS} negated to A(0:31) invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1	38.67		31.38		24.50		17.83		ns
B31	CLKOUT falling edge to \overline{CS} valid—as requested by control bit CST4 in the corresponding word in UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns

		33 MHz		40 MHz		50 MHz		66 MHz		
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B31a	CLKOUT falling edge to CS valid—as requested by control bit CST1 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B31b	CLKOUT rising edge to $\overline{\text{CS}}$ valid—as requested by control bit CST2 in the corresponding word in UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to $\overline{\text{CS}}$ valid—as requested by control bit CST3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.04	ns
B31d	CLKOUT falling edge to \overline{CS} valid—as requested by control bit CST1 in the corresponding word in UPM, EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B32	CLKOUT falling edge to BS valid—as requested by control bit BST4 in the corresponding word in UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to \overline{BS} valid—as requested by control bit BST1 in the corresponding word in UPM, EBDF = 0	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32b	CLKOUT rising edge to $\overline{\text{BS}}$ valid—as requested by control bit BST2 in the corresponding word in UPM	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to $\overline{\text{BS}}$ valid—as requested by control bit BST3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B32d	CLKOUT falling edge to $\overline{\text{BS}}$ valid—as requested by control bit BST1 in the corresponding word in UPM, EBDF = 1	13.26	17.99	11.28	16.00	9.40	14.13	7.58	12.31	ns
B33	CLKOUT falling edge to GPL valid—as requested by control bit GxT4 in the corresponding word in UPM	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B33a	CLKOUT rising edge to GPL valid—as requested by control bit GxT3 in the corresponding word in UPM	7.58	14.33	6.25	13.00	5.00	11.75	3.80	10.54	ns
B34	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid—as requested by control bit CST4 in the corresponding word in UPM	5.58		4.25		3.00		1.79		ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid—as requested by control bit CST1 in the corresponding word in UPM	13.15	_	10.50	_	8.00	_	5.58	—	ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid—as requested by control bit CST2 in the corresponding word in UPM	20.73		16.75		13.00		9.36		ns

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N	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		
Num		Min	Мах	Min	Max	Min	Max	Min	Max	Unit
B35	A(0:31), BADDR(28:30) to \overline{CS} valid—as requested by control bit BST4 in the corresponding word in UPM	5.58		4.25		3.00	_	1.79	_	ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to $\overline{\text{BS}}$ valid—as requested by control bit BST1 in the corresponding word in UPM	13.15	_	10.50	—	8.00	—	5.58	—	ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to $\overline{\text{BS}}$ valid—as requested by control bit BST2 in the corresponding word in UPM	20.73	—	16.75	—	13.00	—	9.36	—	ns
B36	A(0:31), BADDR(28:30), and D(0:31) to GPL valid—as requested by control bit GxT4 in the corresponding word in UPM	5.58	—	4.25	—	3.00	—	1.79	—	ns
B37	UPWAIT valid to CLKOUT falling edge ⁹	6.00	_	6.00	_	6.00		6.00		ns
B38	CLKOUT falling edge to UPWAIT valid ⁹	1.00	_	1.00	_	1.00		1.00		ns
B39	AS valid to CLKOUT rising edge ¹⁰	7.00	_	7.00	_	7.00		7.00		ns
B40	A(0:31), TSIZ(0:1), RD/WR, BURST, valid to CLKOUT rising edge	7.00	—	7.00	_	7.00	_	7.00	_	ns
B41	\overline{TS} valid to CLKOUT rising edge (setup time)	7.00		7.00		7.00		7.00		ns
B42	CLKOUT rising edge to \overline{TS} valid (hold time)	2.00	_	2.00	_	2.00	_	2.00	_	ns
B43	AS negation to memory controller signals negation	—	TBD	—	TBD	—	TBD	—	TBD	ns

¹ Phase and frequency jitter performance results are only valid if the input jitter is less than the prescribed value.

² If the rate of change of the frequency of EXTAL is slow (that is, it does not jump between the minimum and maximum values in one cycle) or the frequency of the jitter is fast (that is, it does not stay at an extreme value for a long time) then the maximum allowed jitter on EXTAL can be up to 2%.

³ The timings specified in B4 and B5 are based on full strength clock.

⁴ The timing for BR output is relevant when the MPC860 is selected to work with external bus arbiter. The timing for BG output is relevant when the MPC860 is selected to work with internal bus arbiter.

⁵ The timing required for BR input is relevant when the MPC860 is selected to work with internal bus arbiter. The timing for BG input is relevant when the MPC860 is selected to work with external bus arbiter.

⁶ The D(0:31) and DP(0:3) input timings B18 and B19 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.

⁷ The D(0:31) and DP(0:3) input timings B20 and B21 refer to the falling edge of the CLKOUT. This timing is valid only for read accesses controlled by chip-selects under control of the UPM in the memory controller, for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

⁸ The timing B30 refers to \overline{CS} when ACS = 00 and to $\overline{WE}(0:3)$ when CSNT = 0.

⁹ The signal UPWAIT is considered asynchronous to the CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals as described in Figure 18.

¹⁰ The AS signal is considered asynchronous to the CLKOUT. The timing B39 is specified in order to allow the behavior specified in Figure 21.

Figure 3 is the control timing diagram.

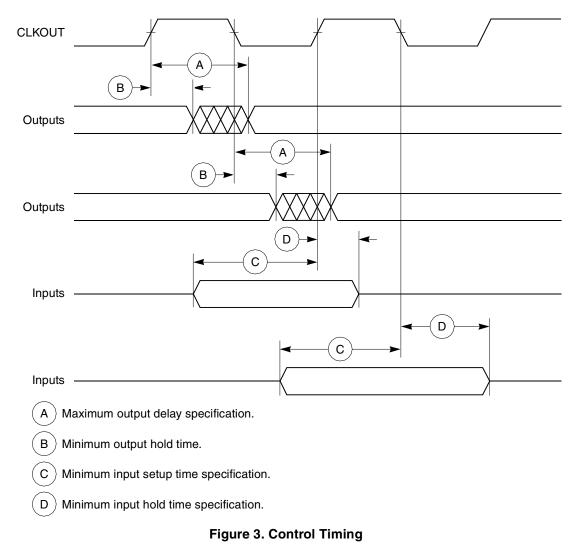


Figure 4 provides the timing for the external clock.

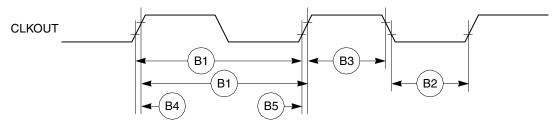


Figure 4. External Clock Timing

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Figure 5 provides the timing for the synchronous output signals.

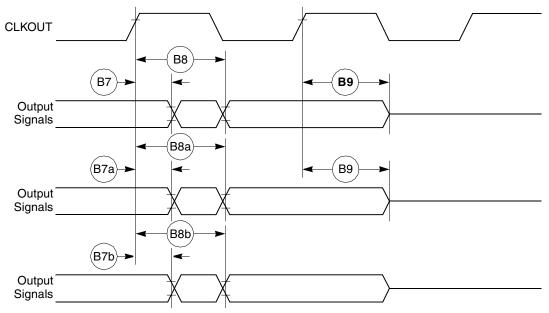


Figure 5. Synchronous Output Signals Timing

Figure 6 provides the timing for the synchronous active pull-up and open-drain output signals.

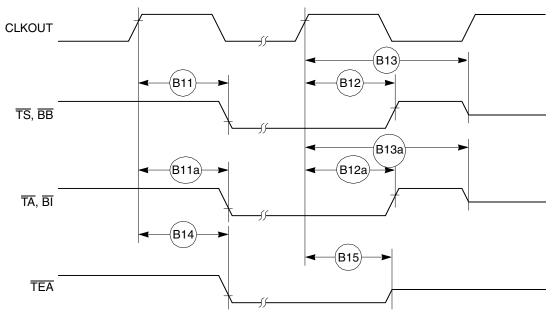


Figure 6. Synchronous Active Pull-Up Resistor and Open-Drain Outputs Signals Timing

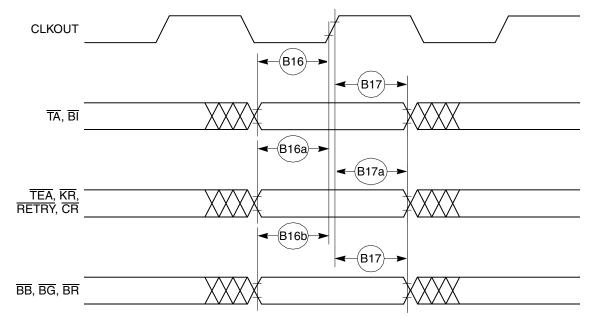


Figure 7 provides the timing for the synchronous input signals.

Figure 7. Synchronous Input Signals Timing

Figure 8 provides normal case timing for input data. It also applies to normal read accesses under the control of the UPM in the memory controller.

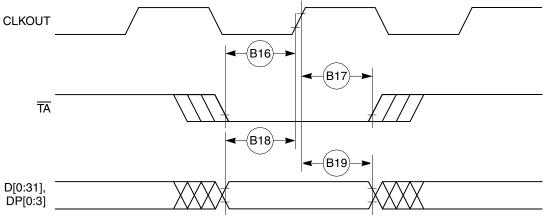


Figure 8. Input Data Timing in Normal Case

Figure 9 provides the timing for the input data controlled by the UPM for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

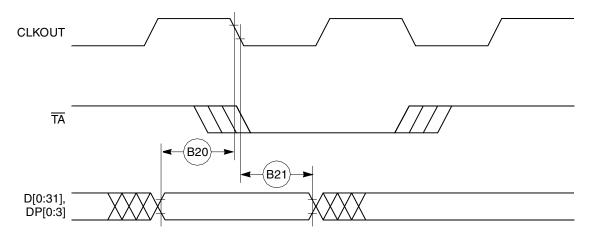
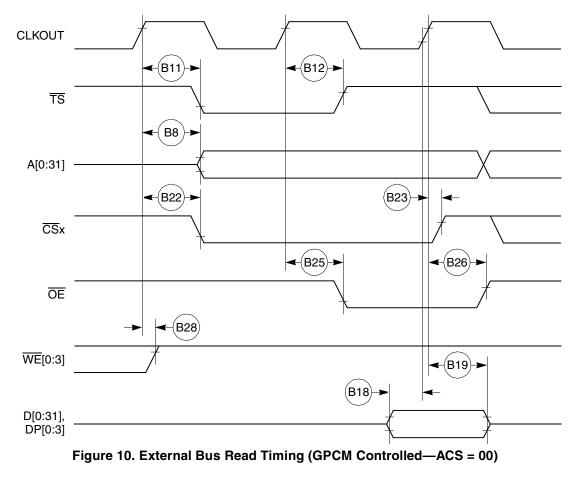
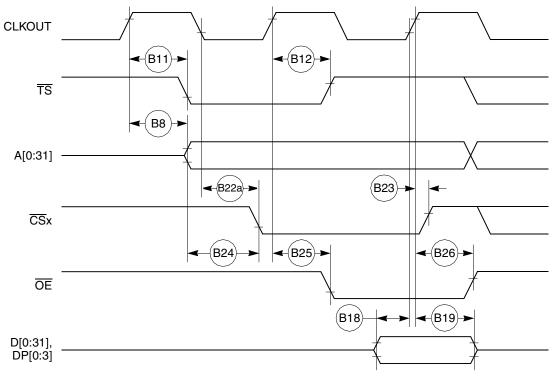


Figure 9. Input Data Timing when Controlled by UPM in the Memory Controller and DLT3 = 1

Figure 10 through Figure 13 provide the timing for the external bus read controlled by various GPCM factors.



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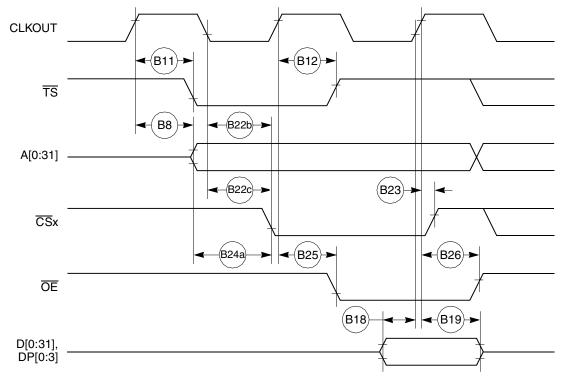


Figure 12. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 11)

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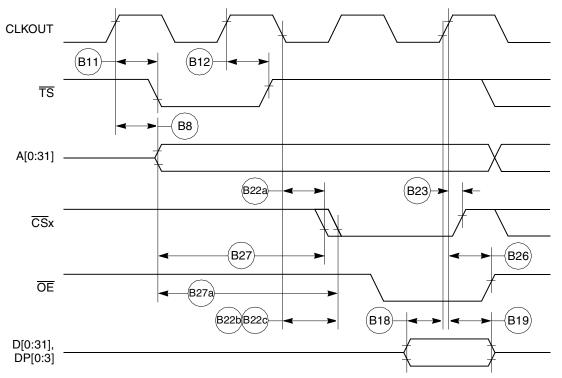


Figure 13. External Bus Read Timing (GPCM Controlled—TRLX = 0 or 1, ACS = 10, ACS = 11)

Figure 14 through Figure 16 provide the timing for the external bus write controlled by various GPCM factors.

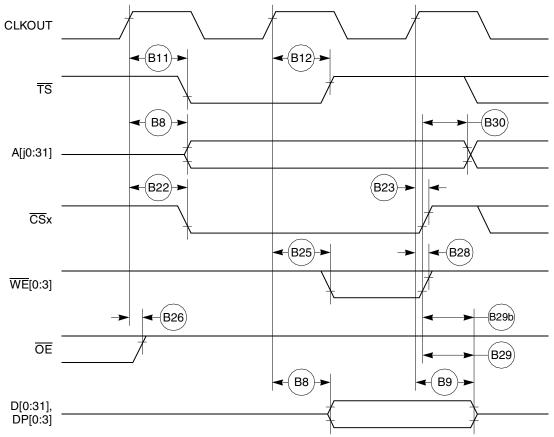


Figure 14. External Bus Write Timing (GPCM Controlled—TRLX = 0 or 1, CSNT = 0)

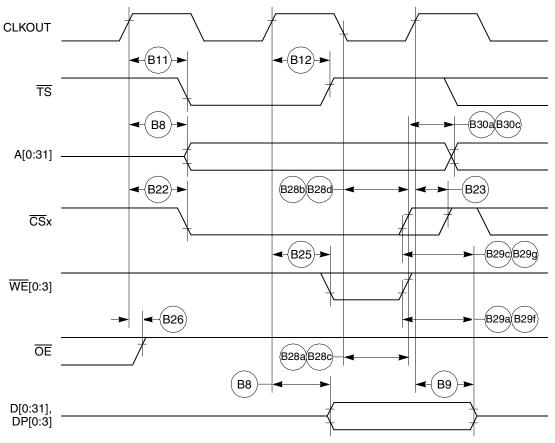


Figure 15. External Bus Write Timing (GPCM Controlled—TRLX = 0 or 1, CSNT = 1)

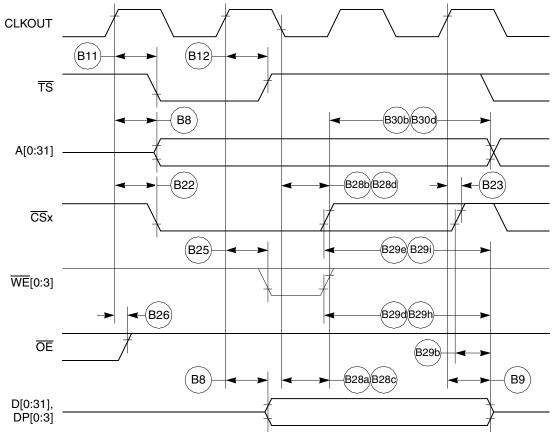


Figure 16. External Bus Write Timing (GPCM Controlled—TRLX = 0 or 1, CSNT = 1)

Figure 17 provides the timing for the external bus controlled by the UPM.

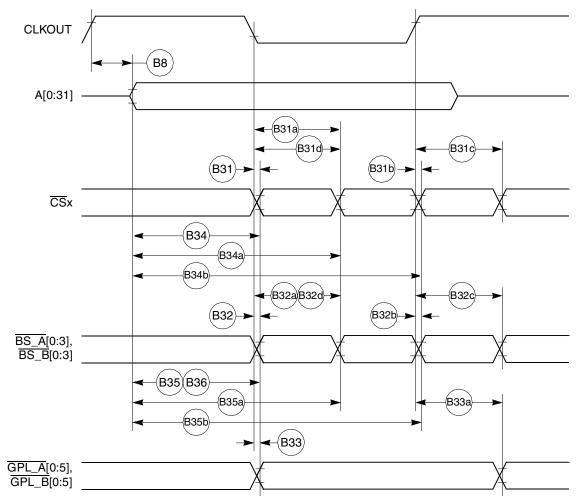


Figure 17. External Bus Timing (UPM Controlled Signals)

Figure 18 provides the timing for the asynchronous asserted UPWAIT signal controlled by the UPM.

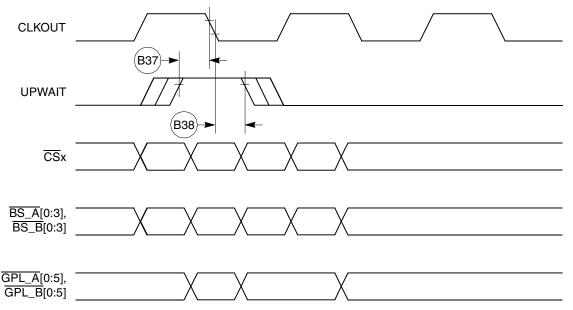


Figure 18. Asynchronous UPWAIT Asserted Detection in UPM Handled Cycles Timing

Figure 19 provides the timing for the asynchronous negated UPWAIT signal controlled by the UPM.

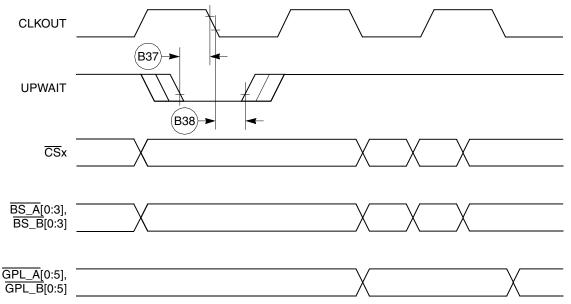


Figure 19. Asynchronous UPWAIT Negated Detection in UPM Handled Cycles Timing

Figure 20 provides the timing for the synchronous external master access controlled by the GPCM.

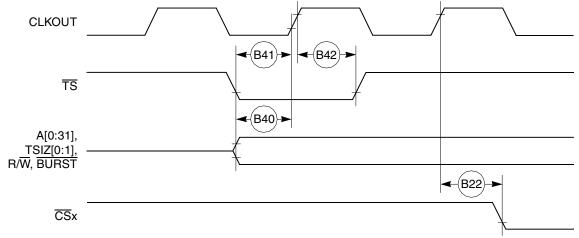
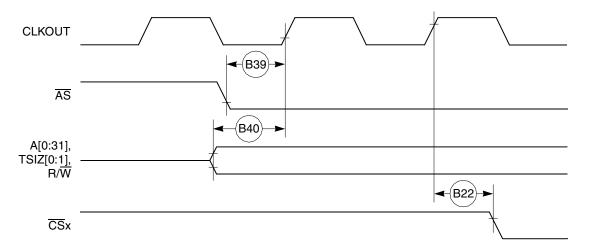


Figure 20. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 21 provides the timing for the asynchronous external master memory access controlled by the GPCM.



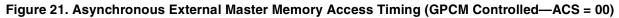


Figure 22 provides the timing for the asynchronous external master control signals negation.

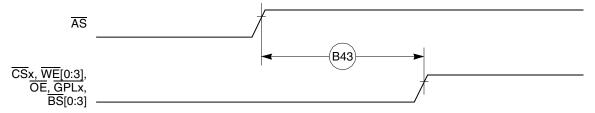


Figure 22. Asynchronous External Master—Control Signals Negation Timing

Table 8 provides interrupt timing for the MPC860.

Num	Characteristic ¹	All Freq	uencies	Unit
	Characteristic	Min	Мах	Unit
139	IRQx valid to CLKOUT rising edge (setup time)	6.00	_	ns
140	IRQx hold time after CLKOUT	2.00	_	ns
141	IRQx pulse width low	3.00	_	ns
142	IRQx pulse width high	3.00	_	ns
143	IRQx edge-to-edge time	$4 \times T_{CLOCKOUT}$	_	_

Table 8. Interrupt Timing

The timings I39 and I40 describe the testing conditions under which the IRQ lines are tested when being defined as level-sensitive. The IRQ lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT.

The timings I41, I42, and I43 are specified to allow the correct function of the IRQ lines detection circuitry and have no direct relation with the total system interrupt latency that the MPC860 is able to support.

Figure 23 provides the interrupt detection timing for the external level-sensitive lines.

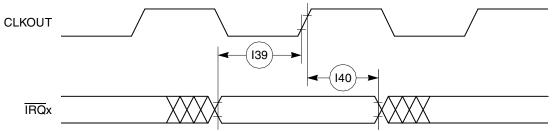


Figure 23. Interrupt Detection Timing for External Level Sensitive Lines

Figure 24 provides the interrupt detection timing for the external edge-sensitive lines.

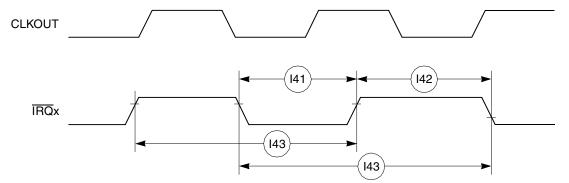


Figure 24. Interrupt Detection Timing for External Edge Sensitive Lines

Table 9 shows the PCMCIA timing for the MPC860.

Table 9. PCMCIA Timing

		33 MHz 4			40.1411		50 MHz			
Num	Characteristic	33 1	MHZ	40 1	MHz	50 1	MHZ	66 I	MHz	Unit
		Min	Max	Min	Max	Min	Max	Min	Max	onne
P44	A(0:31), REG valid to PCMCIA Strobe asserted ¹	20.73	_	16.75	—	13.00	—	9.36	—	ns
P45	A(0:31), $\overline{\text{REG}}$ valid to ALE negation ¹	28.30	_	23.00	—	18.00	—	13.15	_	ns
P46	CLKOUT to REG valid	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P47	CLKOUT to REG invalid	8.58		7.25	—	6.00	—	4.84	—	ns
P48	CLKOUT to CE1, CE2 asserted	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P49	CLKOUT to CE1, CE2 negated	7.58	15.58	6.25	14.25	5.00	13.00	3.79	11.84	ns
P50	CLKOUT to PCOE, IORD, PCWE, IOWR assert time	—	11.00		11.00	_	11.00	—	11.00	ns
P51	CLKOUT to PCOE, IORD, PCWE, IOWR negate time	2.00	11.00	2.00	11.00	2.00	11.00	2.00	11.00	ns
P52	CLKOUT to ALE assert time	7.58	15.58	6.25	14.25	5.00	13.00	3.79	10.04	ns
P53	CLKOUT to ALE negate time	—	15.58		14.25	_	13.00	—	11.84	ns
P54	PCWE, IOWR negated to D(0:31) invalid ¹	5.58	_	4.25	—	3.00	—	1.79	_	ns
P55	WAITA and WAITB valid to CLKOUT rising edge ¹	8.00	_	8.00	_	8.00	_	8.00	_	ns
P56	CLKOUT rising edge to WAITA and WAITB invalid ¹	2.00	_	2.00	—	2.00	—	2.00	—	ns

¹ PSST = 1. Otherwise add PSST times cycle time.

PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the $\overline{\text{WAITx}}$ signals are detected in order to freeze (or relieve) the PCMCIA current cycle. The $\overline{\text{WAITx}}$ assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See Chapter 16, "PCMCIA Interface," in the *MPC860 PowerQUICC*TM Family User's Manual.

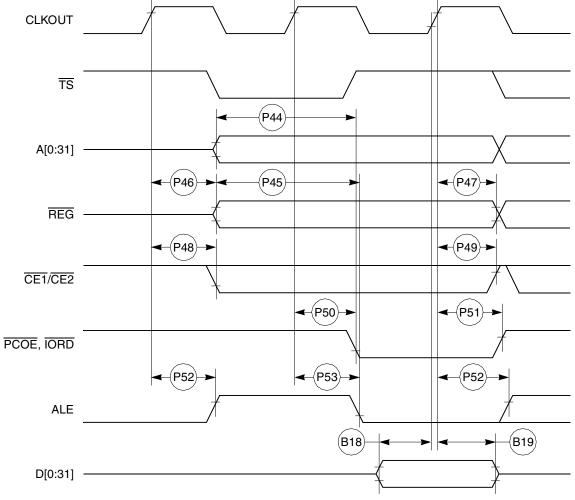


Figure 25 provides the PCMCIA access cycle timing for the external bus read.

Figure 25. PCMCIA Access Cycle Timing External Bus Read

Figure 26 provides the PCMCIA access cycle timing for the external bus write.

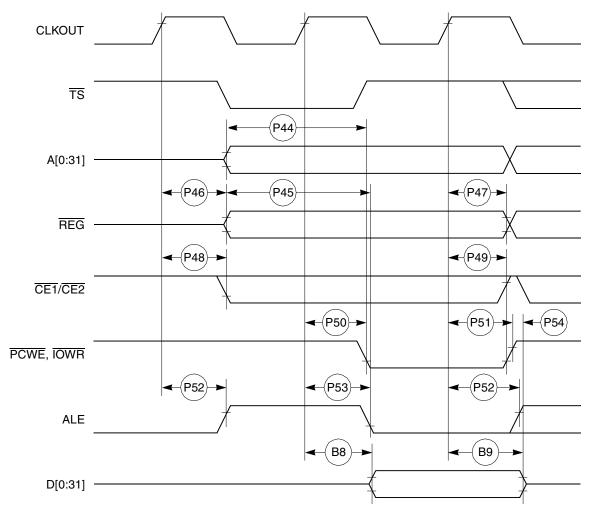


Figure 26. PCMCIA Access Cycle Timing External Bus Write

Figure 27 provides the PCMCIA \overline{WAIT} signal detection timing.

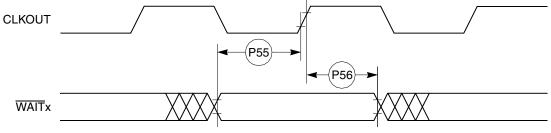


Figure 27. PCMCIA WAIT Signal Detection Timing

Table 10 shows the PCMCIA port timing for the MPC860.

Table 10. PCMCIA Port Timing

Num	Characteristic	33	MHz	40 1	MHz	50 MHz		66 MHz		Unit
	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit ns
P57	CLKOUT to OPx valid	_	19.00	—	19.00	_	19.00	—	19.00	ns
P58	HRESET negated to OPx drive ¹	25.73		21.75	—	18.00	—	14.36	-	ns
P59	IP_Xx valid to CLKOUT rising edge	5.00	_	5.00	_	5.00	—	5.00	_	ns
P60	CLKOUT rising edge to IP_Xx invalid	1.00	_	1.00	—	1.00	_	1.00	_	ns

¹ OP2 and OP3 only.

Figure 28 provides the PCMCIA output port timing for the MPC860.

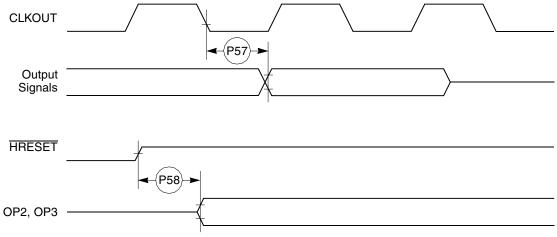


Figure 28. PCMCIA Output Port Timing

Figure 29 provides the PCMCIA output port timing for the MPC860.

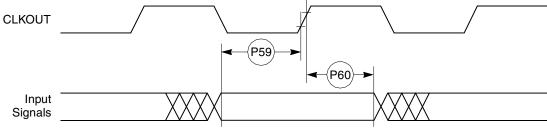


Figure 29. PCMCIA Input Port Timing

Bus Signal Timing

Table 11 shows the debug port timing for the MPC860.

Table 11. Debug Port Timing

Num	Characteristic	All Frequencies		Unit
Nulli	Characteristic	Min	Мах	onit
P61	DSCK cycle time	3 × T _{CLOCKOUT}	_	—
P62	DSCK clock pulse width	$1.25 imes T_{CLOCKOUT}$	_	—
P63	DSCK rise and fall times	0.00	3.00	ns
P64	DSDI input data setup time	8.00	_	ns
P65	DSDI data hold time	5.00	_	ns
P66	DSCK low to DSDO data valid	0.00	15.00	ns
P67	DSCK low to DSDO invalid	0.00	2.00	ns

Figure 30 provides the input timing for the debug port clock.

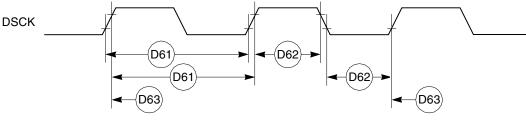


Figure 30. Debug Port Clock Input Timing

Figure 31 provides the timing for the debug port.

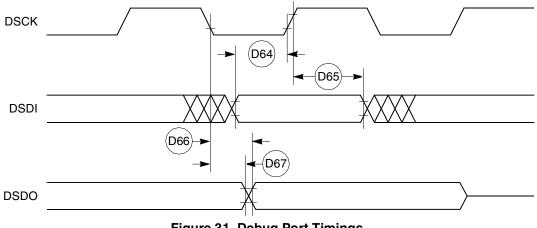


Figure 31. Debug Port Timings

Table 12 shows the reset timing for the MPC860.

Table 12. Reset Timing

	Oh ann atariatha	33 N	/IHz	40 N	/Hz	50 N	ΛHz	66 N	/IHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
R69	CLKOUT to HRESET high impedance	_	20.00	_	20.00		20.00	_	20.00	ns
R70	CLKOUT to SRESET high impedance	—	20.00	—	20.00	_	20.00	—	20.00	ns
R71	RSTCONF pulse width	515.15	_	425.00		340.00	_	257.58	_	ns
R72	_							_		
R73	Configuration data to HRESET rising edge setup time	504.55	—	425.00	—	350.00	—	277.27	—	ns
R74	Configuration data to RSTCONF rising edge setup time	350.00	_	350.00	_	350.00	_	350.00	_	ns
R75	Configuration data hold time after RSTCONF negation	0.00	_	0.00	_	0.00	_	0.00	_	ns
R76	Configuration data hold time after HRESET negation	0.00	—	0.00	—	0.00	—	0.00	—	ns
R77	HRESET and RSTCONF asserted to data out drive	_	25.00		25.00	—	25.00	—	25.00	ns
R78	RSTCONF negated to data out high impedance	—	25.00	—	25.00	—	25.00	—	25.00	ns
R79	CLKOUT of last rising edge before chip three-state HRESET to data out high impedance	_	25.00	_	25.00	_	25.00	_	25.00	ns
R80	DSDI, DSCK setup	90.91	—	75.00	—	60.00	—	45.45	—	ns
R81	DSDI, DSCK hold time	0.00	—	0.00	—	0.00	—	0.00	_	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample	242.42	—	200.00	—	160.00	—	121.21		ns

Bus Signal Timing

Figure 32 shows the reset timing for the data bus configuration.

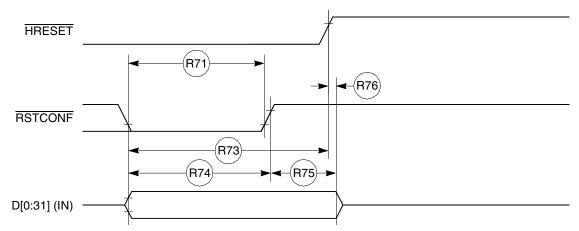


Figure 32. Reset Timing—Configuration from Data Bus

Figure 33 provides the reset timing for the data bus weak drive during configuration.

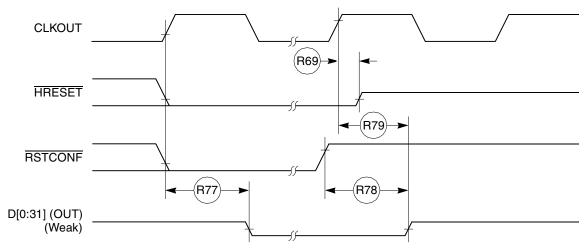


Figure 33. Reset Timing—Data Bus Weak Drive During Configuration

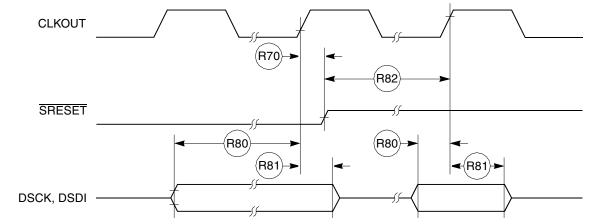


Figure 34 provides the reset timing for the debug port configuration.

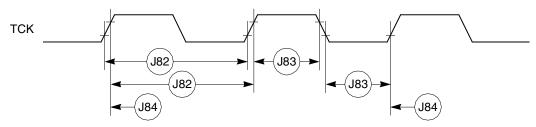
Figure 34. Reset Timing—Debug Port Configuration

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Table 13 provides the JTAG timings for the MPC860 shown in Figure 35 through Figure 38.

Num	Characteristic	All Frequencies		Unit
Num	Characteristic	Min	Мах	
J82	TCK cycle time	100.00		ns
J83	TCK clock pulse width measured at 1.5 V	40.00	—	ns
J84	TCK rise and fall times	0.00	10.00	ns
J85	TMS, TDI data setup time	5.00	—	ns
J86	TMS, TDI data hold time	25.00	—	ns
J87	TCK low to TDO data valid		27.00	ns
J88	TCK low to TDO data invalid	0.00	—	ns
J89	TCK low to TDO high impedance		20.00	ns
J90	TRST assert time	100.00	—	ns
J91	TRST setup time to TCK low	40.00	—	ns
J92	TCK falling edge to output valid	—	50.00	ns
J93	TCK falling edge to output valid out of high impedance		50.00	ns
J94	TCK falling edge to output high impedance	_	50.00	ns
J95	Boundary scan input valid to TCK rising edge	50.00	—	ns
J96	TCK rising edge to boundary scan input invalid	50.00	—	ns

Table 13. JTAG Timing





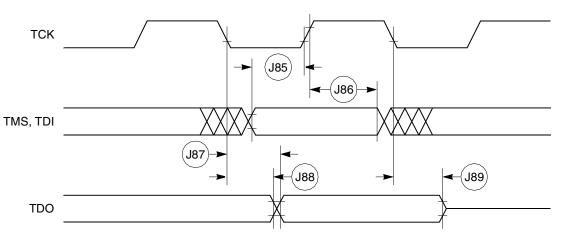


Figure 36. JTAG Test Access Port Timing Diagram

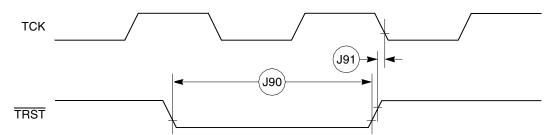


Figure 37. JTAG TRST Timing Diagram

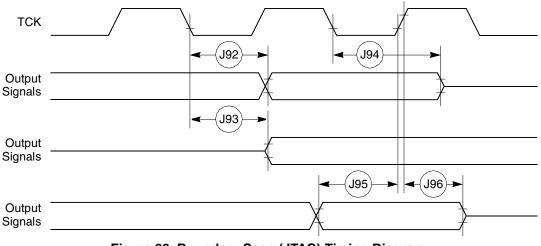


Figure 38. Boundary Scan (JTAG) Timing Diagram

11 CPM Electrical Characteristics

This section provides the AC and DC electrical specifications for the communications processor module (CPM) of the MPC860.

11.1 PIP/PIO AC Electrical Specifications

Table 14 provides the PIP/PIO AC timings as shown in Figure 39 through Figure 43.

Table 14. PIP/PIO Timing

Num	Characteristic	All Frequencies		Unit
Num	Characteristic	Min Max	Max	Omit
21	Data-in setup time to STBI low	0	_	ns
22	Data-in hold time to STBI high	2.5 - t3 ¹	_	CLK
23	STBI pulse width	1.5	_	CLK
24	STBO pulse width	1 CLK – 5 ns	_	ns
25	Data-out setup time to STBO low	2	_	CLK
26	Data-out hold time from STBO high	5	_	CLK
27	STBI low to STBO low (Rx interlock)	—	2	CLK
28	STBI low to STBO high (Tx interlock)	2	_	CLK
29	Data-in setup time to clock high	15	_	ns
30	Data-in hold time from clock high	7.5	_	ns
31	Clock low to data-out valid (CPU writes data, control, or direction)	—	25	ns

¹ t3 = Specification 23.

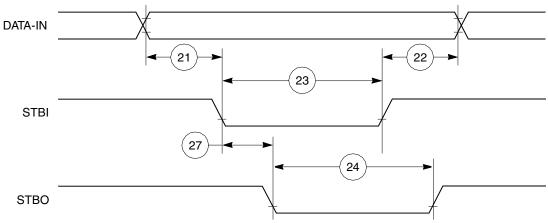
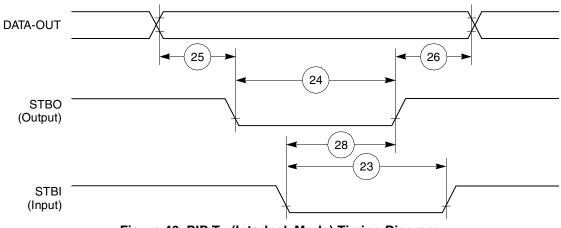


Figure 39. PIP Rx (Interlock Mode) Timing Diagram





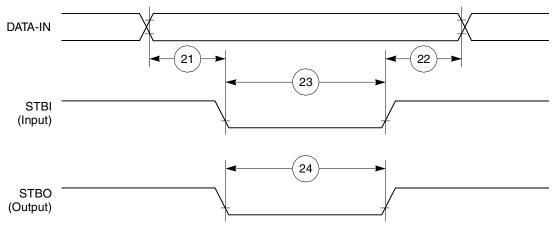


Figure 41. PIP Rx (Pulse Mode) Timing Diagram

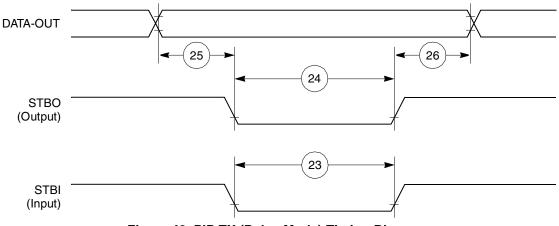


Figure 42. PIP TX (Pulse Mode) Timing Diagram

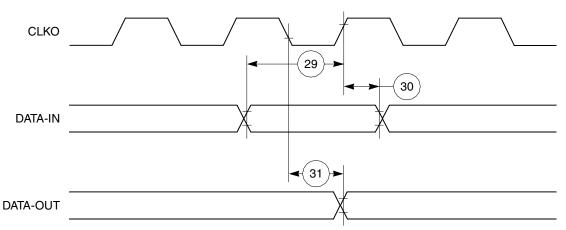


Figure 43. Parallel I/O Data-In/Data-Out Timing Diagram

11.2 Port C Interrupt AC Electrical Specifications

Table 15 provides the timings for port C interrupts.

Table	15. Port	C Interrupt	Timing
-------	----------	-------------	--------

Num	Characteristic	≥ 33.34 MHz ¹		Unit
Num	Unaracteristic	Min Max	Onit	
35	Port C interrupt pulse width low (edge-triggered mode)	55	_	ns
36	Port C interrupt minimum time between active edges	55		ns

¹ External bus frequency of greater than or equal to 33.34 MHz.

Figure 44 shows the port C interrupt detection timing.

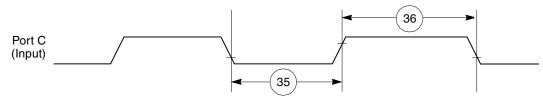


Figure 44. Port C Interrupt Detection Timing

11.3 IDMA Controller AC Electrical Specifications

Table 16 provides the IDMA controller timings as shown in Figure 45 through Figure 48.

Table 16. IDMA Controller Timing

Num	Characteristic	All Frequencies		Unit
	Characteristic	Min Max	Unit	
40	DREQ setup time to clock high	7	_	ns
41	DREQ hold time from clock high	3		ns

Num	Characteristic	All Frequencies		Unit
Num	Characteristic	Min	Min Max	
42	SDACK assertion delay from clock high	_	12	ns
43	SDACK negation delay from clock low	—	12	ns
44	SDACK negation delay from TA low		20	ns
45	SDACK negation delay from clock high		15	ns
46	\overline{TA} assertion to rising edge of the clock setup time (applies to external \overline{TA})	7	_	ns



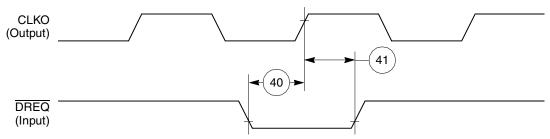


Figure 45. IDMA External Requests Timing Diagram

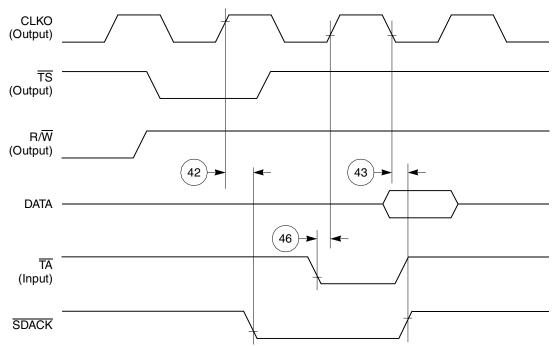


Figure 46. SDACK Timing Diagram—Peripheral Write, Externally-Generated TA

CPM Electrical Characteristics

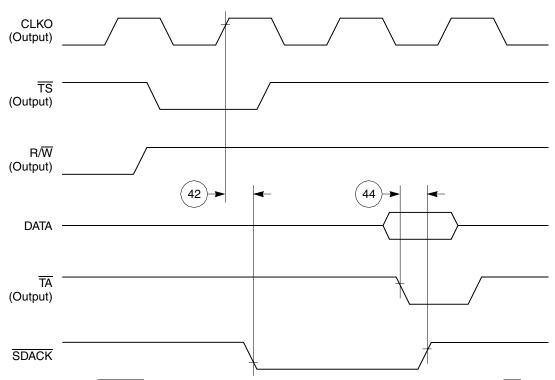


Figure 47. SDACK Timing Diagram—Peripheral Write, Internally-Generated TA

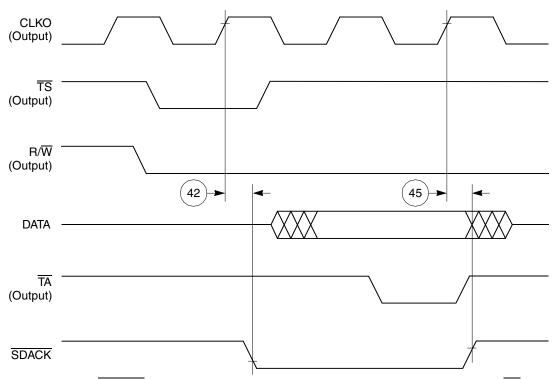


Figure 48. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA

11.4 Baud Rate Generator AC Electrical Specifications

Table 17 provides the baud rate generator timings as shown in Figure 49.

Num	Chavastavistis	All Frequencies		Unit
Num	Characteristic	Min	Max 10	Unit
50	BRGO rise and fall time	_	10	ns
51	BRGO duty cycle	40	60	%
52	BRGO cycle	40	—	ns

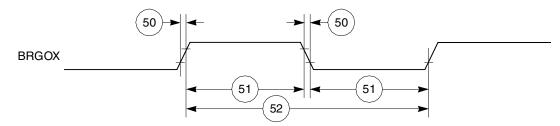


Figure 49. Baud Rate Generator Timing Diagram

11.5 Timer AC Electrical Specifications

Table 18 provides the general-purpose timer timings as shown in Figure 50.

Table 18. Timer Timing

Neuro	Chavastavistia	All Frequencies		Unit
Num	Characteristic	Min	Max Max — — — — — 25	Unit
61	TIN/TGATE rise and fall time	10	_	ns
62	TIN/TGATE low time	1	_	CLK
63	TIN/TGATE high time	2	—	CLK
64	TIN/TGATE cycle time	3	—	CLK
65	CLKO low to TOUT valid	3	25	ns

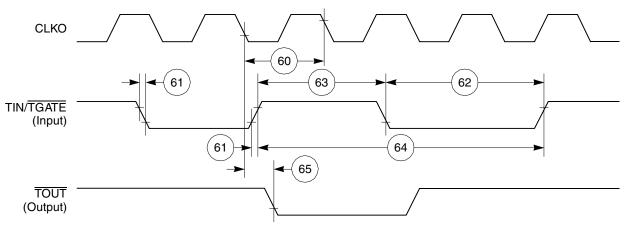


Figure 50. CPM General-Purpose Timers Timing Diagram

11.6 Serial Interface AC Electrical Specifications

Table 19 provides the serial interface timings as shown in Figure 51 through Figure 55.

Num		All Free	quencies	Unit
Num	Characteristic	Min	Max	
70	L1RCLK, L1TCLK frequency (DSC = 0) ^{1, 2}	_	SYNCCLK/2.5	MHz
71	L1RCLK, L1TCLK width low $(DSC = 0)^2$	P + 10	_	ns
71a	L1RCLK, L1TCLK width high (DSC = 0) ³	P + 10	_	ns
72	L1TXD, L1ST(1-4), L1RQ, L1CLKO rise/fall time	-	15.00	ns
73	L1RSYNC, L1TSYNC valid to L1CLK edge (SYNC setup time)	20.00	_	ns
74	L1CLK edge to L1RSYNC, L1TSYNC, invalid (SYNC hold time)	35.00	_	ns
75	L1RSYNC, L1TSYNC rise/fall time		15.00	ns
76	L1RXD valid to L1CLK edge (L1RXD setup time)	17.00	—	ns
77	L1CLK edge to L1RXD invalid (L1RXD hold time)	13.00	—	ns
78	L1CLK edge to L1ST(1-4) valid ⁴	10.00	45.00	ns
78A	L1SYNC valid to L1ST(1-4) valid	10.00	45.00	ns
79	L1CLK edge to L1ST(1-4) invalid	10.00	45.00	ns
80	L1CLK edge to L1TXD valid	10.00	55.00	ns
80A	L1TSYNC valid to L1TXD valid ⁴	10.00	55.00	ns
81	L1CLK edge to L1TXD high impedance	0.00	42.00	ns
82	L1RCLK, L1TCLK frequency (DSC =1)	_	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC = 1)	P + 10	—	ns
83a	L1RCLK, L1TCLK width high (DSC = 1) ³	P + 10	—	ns

Table 19. SI Timing

Nume	Oberneteristis	All Frequencies		11
Num	Characteristic	Min	Мах	Unit ns L1TCL K
84	L1CLK edge to L1CLKO valid (DSC = 1)	_	30.00	ns
85	LIRQ valid before falling edge of L1TSYNC ⁴	1.00	—	-
86	L1GR setup time ²	42.00	—	ns
87	L1GR hold time	42.00	—	ns
88	L1CLK edge to L1SYNC valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	_	0.00	ns

Table 19. SI Timing (continued)

¹ The ratio SYNCCLK/L1RCLK must be greater than 2.5/1.

² These specs are valid for IDL mode only.

³ Where P = 1/CLKOUT. Thus, for a 25-MHz CLKO1 rate, P = 40 ns.

⁴ These strobes and TxD on the first bit of the frame become valid after L1CLK edge or L1SYNC, whichever comes later.

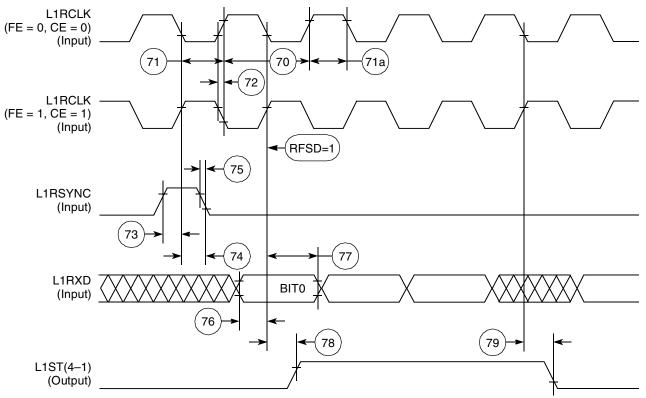
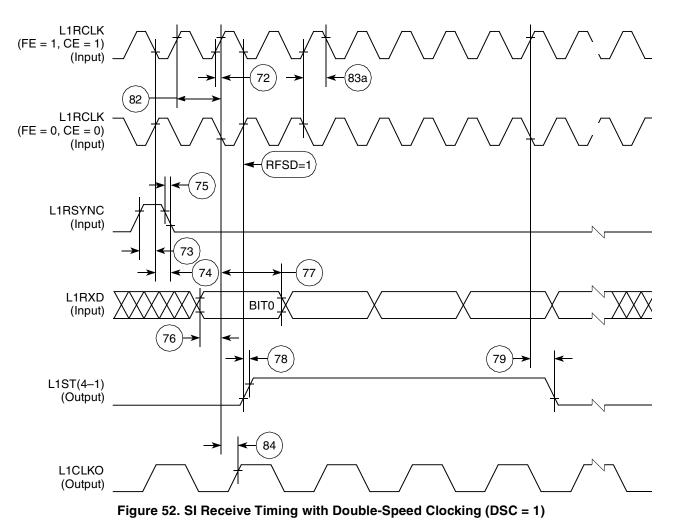
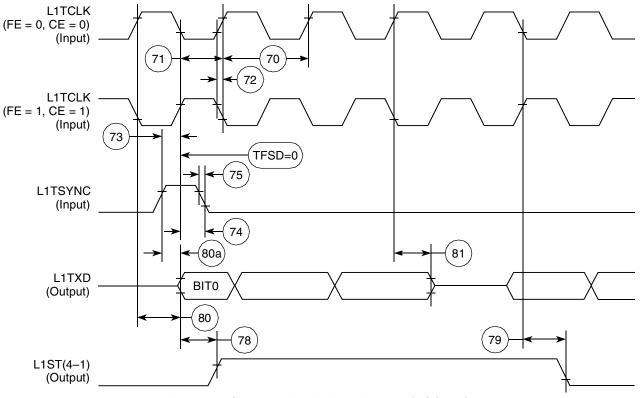


Figure 51. SI Receive Timing Diagram with Normal Clocking (DSC = 0)

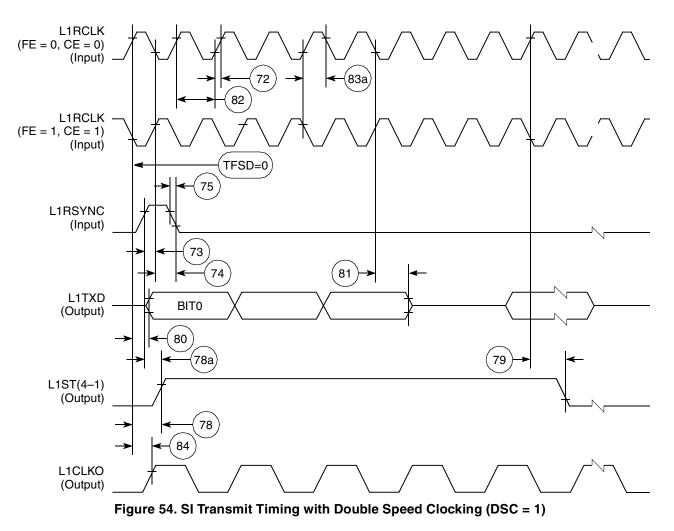
CPM Electrical Characteristics





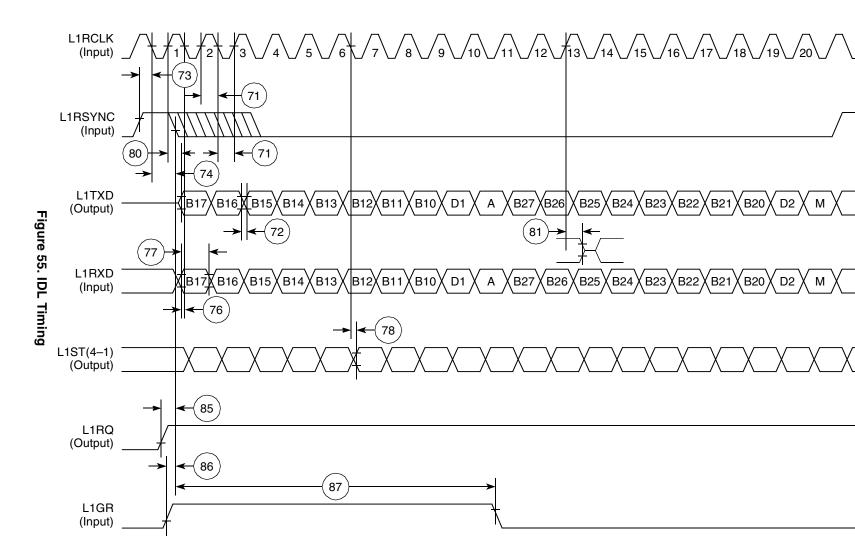


CPM Electrical Characteristics





MPC860 PowerQUICC Family Hardware Specifications, Rev. 9



ъ 4

SCC in NMSI Mode Electrical Specifications 11.7

Table 20 provides the NMSI external clock timing.

		All Frequencies	All Frequencies	
Num	Characteristic	Min	Max	– Unit
100	RCLK1 and TCLK1 width high ¹	1/SYNCCLK	_	ns
101	RCLK1 and TCLK1 width low	1/SYNCCLK + 5		ns
102	RCLK1 and TCLK1 rise/fall time	—	15.00	ns
103	TXD1 active delay (from TCLK1 falling edge)	0.00	50.00	ns
104	RTS1 active/inactive delay (from TCLK1 falling edge)	0.00	50.00	ns
105	CTS1 setup time to TCLK1 rising edge	5.00	—	ns
106	RXD1 setup time to RCLK1 rising edge	5.00	—	ns
107	RXD1 hold time from RCLK1 rising edge ²	5.00	_	ns
108	CD1 setup Time to RCLK1 rising edge	5.00		ns

Table 20. NMSI External Clock Timing

The ratios SYNCCLK/RCLK1 and SYNCCLK/TCLK1 must be greater than or equal to 2.25/1.
 Also applies to CD and CTS hold time when they are used as external sync signals.

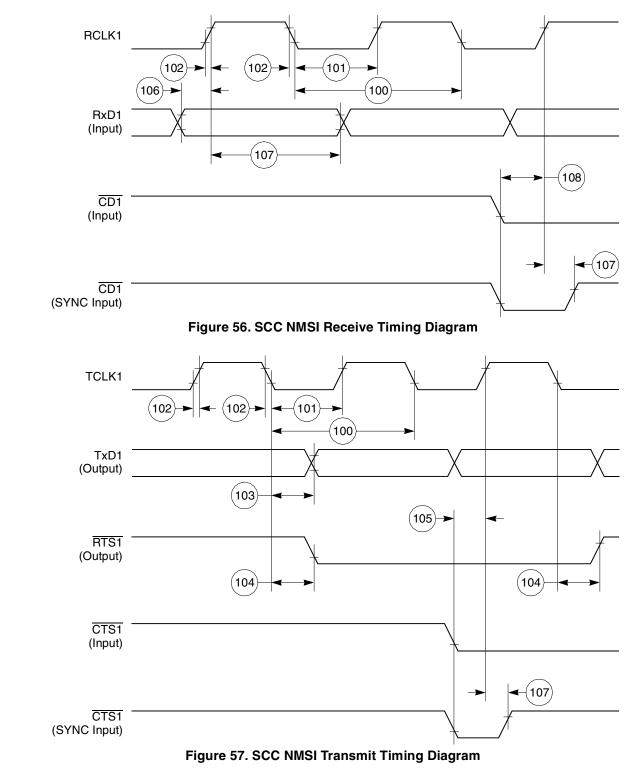
Table 21 provides the NMSI internal clock timing.

Table 21. NMSI Internal Clock Timing

Num	Characteristic	All Freq	All Frequencies	Unit
num	Cildiacteristic	Min	Мах	Unit
100	RCLK1 and TCLK1 frequency ¹	0.00	SYNCCLK/3	MHz
102	RCLK1 and TCLK1 rise/fall time	_	—	ns
103	TXD1 active delay (from TCLK1 falling edge)	0.00	30.00	ns
104	RTS1 active/inactive delay (from TCLK1 falling edge)	0.00	30.00	ns
105	CTS1 setup time to TCLK1 rising edge	40.00	—	ns
106	RXD1 setup time to RCLK1 rising edge	40.00	—	ns
107	RXD1 hold time from RCLK1 rising edge ²	0.00	—	ns
108	CD1 setup time to RCLK1 rising edge	40.00	_	ns

The ratios SYNCCLK/RCLK1 and SYNCCLK/TCLK1 must be greater than or equal to 3/1.
 Also applies to CD and CTS hold time when they are used as external sync signals.

Figure 56 through Figure 58 show the NMSI timings.



CPM Electrical Characteristics

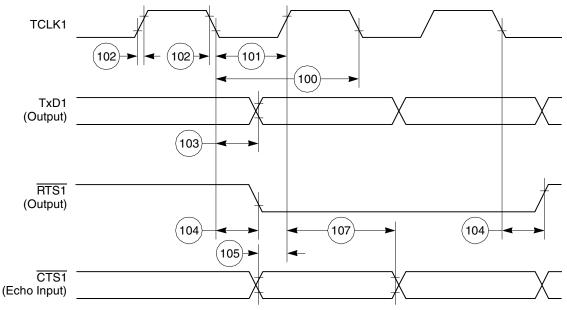


Figure 58. HDLC Bus Timing Diagram

11.8 Ethernet Electrical Specifications

Table 22 provides the Ethernet timings as shown in Figure 59 through Figure 63.

Num	Oberresterristie	All Freq	uencies	Unit
Num	Characteristic	Min	Мах	
120	CLSN width high	40	_	ns
121	RCLK1 rise/fall time	—	15	ns
122	RCLK1 width low	40	—	ns
123	RCLK1 clock period ¹	80	120	ns
124	RXD1 setup time	20	—	ns
125	RXD1 hold time	5	—	ns
126	RENA active delay (from RCLK1 rising edge of the last data bit)	10	—	ns
127	RENA width low	100	—	ns
128	TCLK1 rise/fall time	—	15	ns
129	TCLK1 width low	40	—	ns
130	TCLK1 clock period ¹	99	101	ns
131	TXD1 active delay (from TCLK1 rising edge)	10	50	ns
132	TXD1 inactive delay (from TCLK1 rising edge)	10	50	ns
133	TENA active delay (from TCLK1 rising edge)	10	50	ns
134	TENA inactive delay (from TCLK1 rising edge)	10	50	ns

Num	Characteristic	All Freq	All Frequencies	
Num	Characteristic	Min	Мах	- Unit ns ns CLK
135	RSTRT active delay (from TCLK1 falling edge)	10	50	ns
136	RSTRT inactive delay (from TCLK1 falling edge)	10	50	ns
137	REJECT width low	1	—	CLK
138	CLKO1 low to SDACK asserted ²	—	20	ns
139	CLKO1 low to SDACK negated ²	—	20	ns

Table 22. Ethernet Timing (continued)

¹ The ratios SYNCCLK/RCLK1 and SYNCCLK/TCLK1 must be greater than or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.

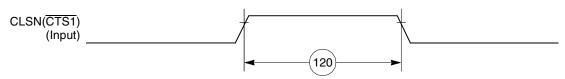


Figure 59. Ethernet Collision Timing Diagram

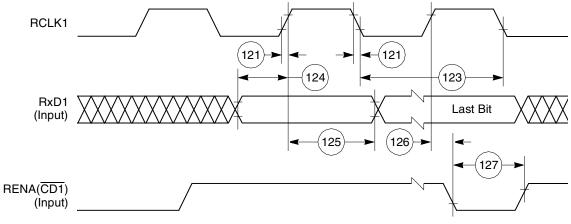
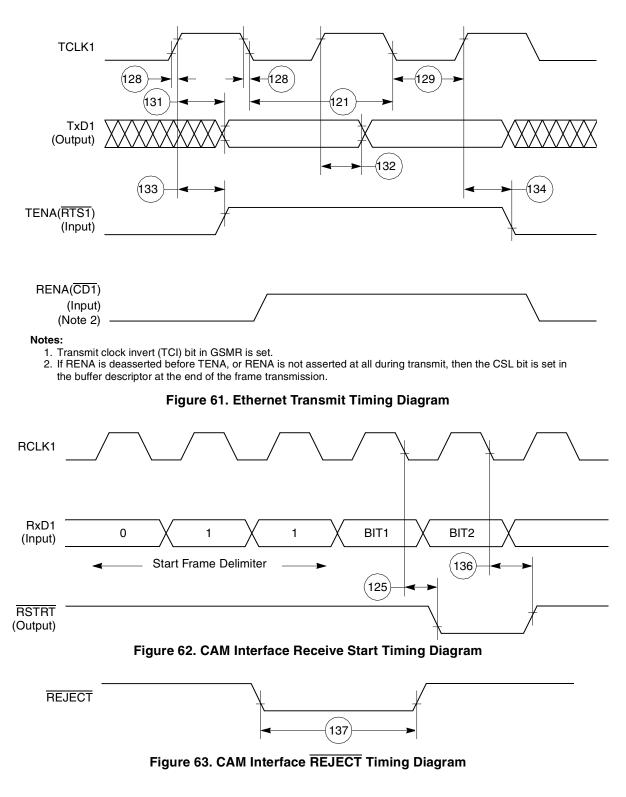


Figure 60. Ethernet Receive Timing Diagram

CPM Electrical Characteristics



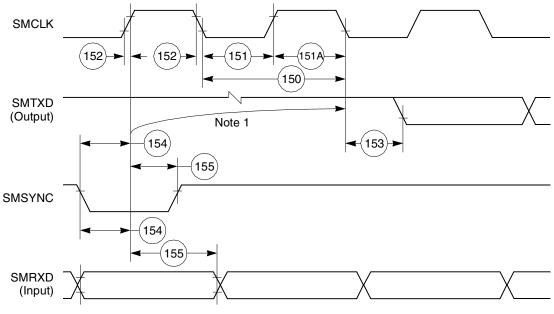
11.9 **SMC Transparent AC Electrical Specifications**

Table 23 provides the SMC transparent timings as shown in Figure 64.

Table 23.	SMC	Transparent	Timing
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Num	Ohavastavistis	All Freq	uencies	11
	Characteristic	Min	Мах	Unit
150	SMCLK clock period ¹	100	—	ns
151	SMCLK width low	50	—	ns
151A	SMCLK width high	50	—	ns
152	SMCLK rise/fall time	—	15	ns
153	SMTXD active delay (from SMCLK falling edge)	10	50	ns
154	SMRXD/SMSYNC setup time	20	—	ns
155	RXD1/SMSYNC hold time	5	—	ns

¹ SYNCCLK must be at least twice as fast as SMCLK.



Note: 1. This delay is equal to an integer number of character-length clocks.

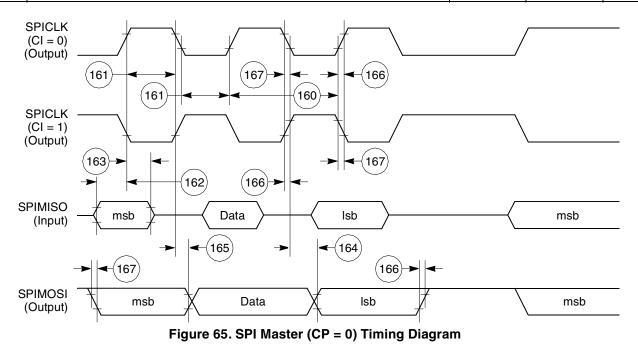


11.10 SPI Master AC Electrical Specifications

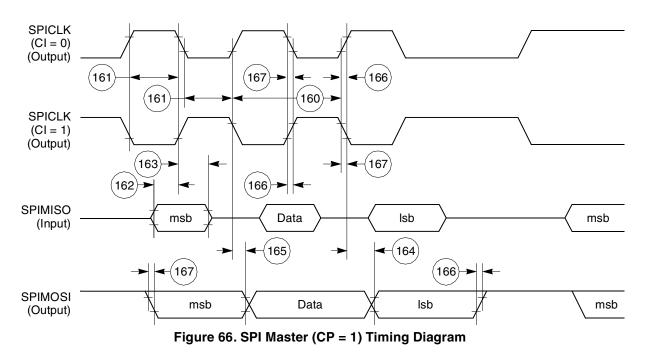
Table 24 provides the SPI master timings as shown in Figure 65 and Figure 66.

Table 24. SPI Master Timing

Num	Characteristic	All Freq	quencies	l lucit
Num	Characteristic	Min	Мах	Unit
160	MASTER cycle time	4	1024	t _{cyc}
161	MASTER clock (SCK) high or low time	2	512	t _{cyc}
162	MASTER data setup time (inputs)	50	—	ns
163	Master data hold time (inputs)	0	—	ns
164	Master data valid (after SCK edge)	_	20	ns
165	Master data hold time (outputs)	0	—	ns
166	Rise time output	—	15	ns
167	Fall time output	—	15	ns



CPM Electrical Characteristics

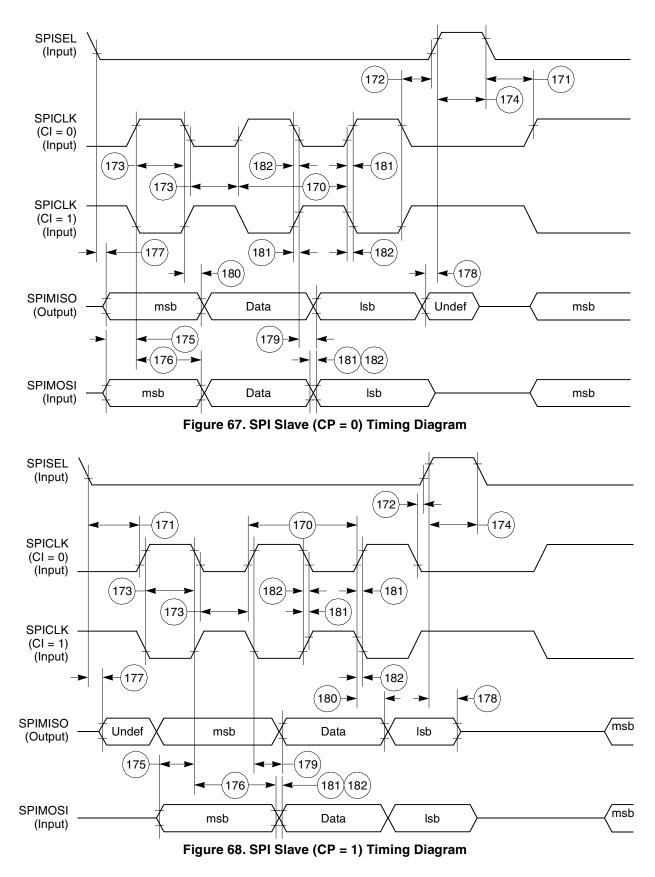


11.11 SPI Slave AC Electrical Specifications

Table 25 provides the SPI slave timings as shown in Figure 67 and Figure 68.

Table 25. SPI Slave Timing

Num	Characteristic	All Freq	quencies	Unit
Nulli	Characteristic	Min	Мах	Unit
170	Slave cycle time	2	—	t _{cyc}
171	Slave enable lead time	15	—	ns
172	Slave enable lag time	15	—	ns
173	Slave clock (SPICLK) high or low time	1	—	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	—	t _{cyc}
175	Slave data setup time (inputs)	20	—	ns
176	Slave data hold time (inputs)	20	—	ns
177	Slave access time	_	50	ns



11.12 I²C AC Electrical Specifications

Table 26 provides the I^2C (SCL < 100 kHz) timings.

Table 26. I²C Timing (SCL < 100 kHz)

Num	Characteristic	All Freq	uencies	All Frequencies	
Num	Characteristic	Min	Max	Unit	
200	SCL clock frequency (slave)	0	100	kHz	
200	SCL clock frequency (master) ¹	1.5	100	kHz	
202	Bus free time between transmissions	4.7	_	μs	
203	Low period of SCL	4.7	_	μs	
204	High period of SCL	4.0	_	μs	
205	Start condition setup time	4.7	_	μs	
206	Start condition hold time	4.0	_	μs	
207	Data hold time	0	_	μs	
208	Data setup time	250	_	ns	
209	SDL/SCL rise time	—	1	μs	
210	SDL/SCL fall time	—	300	ns	
211	Stop condition setup time	4.7	—	μs	

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3 × pre_scaler × 2). The ratio SYNCCLK/(BRGCLK/pre_scaler) must be greater than or equal to 4/1.

Table 27 provides the I^2C (SCL > 100 kHz) timings.

Table 27. . I²C Timing (SCL > 100 kHz)

Num	Characteristic	Expression	All Freq	Unit	
Num	Gharacteristic	Expression	Min	Мах	Omit
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions		1/(2.2 * fSCL)	—	s
203	Low period of SCL		1/(2.2 * fSCL)	—	s
204	High period of SCL		1/(2.2 * fSCL)	—	s
205	Start condition setup time		1/(2.2 * fSCL)	—	s
206	Start condition hold time		1/(2.2 * fSCL)	_	S
207	Data hold time		0	—	s
208	Data setup time		1/(40 * fSCL)	_	S
209	SDL/SCL rise time		—	1/(10 * fSCL)	s
210	SDL/SCL fall time		—	1/(33 * fSCL)	S
211	Stop condition setup time		1/2(2.2 * fSCL)	_	S

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3) × pre_scaler × 2). The ratio SYNCCLK/(BRGCLK / pre_scaler) must be greater than or equal to 4/1.

Figure 69 shows the I^2C bus timing.

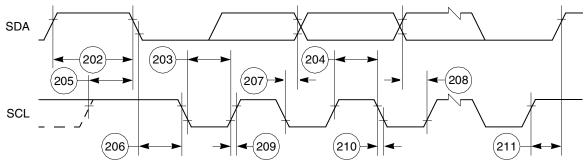


Figure 69. I²C Bus Timing Diagram

12 UTOPIA AC Electrical Specifications

Table 28 shows the AC electrical specifications for the UTOPIA interface.

Num	Signal Characteristic	Direction	Min	Мах	Unit
U1	UtpClk rise/fall time (Internal clock option)	Output	_	3.5	ns
	Duty cycle		50	50	%
	Frequency		_	50	MHz
U1a	UtpClk rise/fall time (external clock option)	Input	_	3.5	ns
	Duty cycle		40	60	%
	Frequency		_	50	MHz
U2	RxEnb and TxEnb active delay	Output	2	16	ns
U3	UTPB, SOC, Rxclav and Txclav setup time	Input	8	—	ns
U4	UTPB, SOC, Rxclav and Txclav hold time	Input	1	—	ns
U5	UTPB, SOC active delay (and PHREQ and PHSEL active delay in MPHY mode)	Output	2	16	ns

Table 28. UTOPIA AC Electrical Specifications



Figure 70 shows signal timings during UTOPIA receive operations.

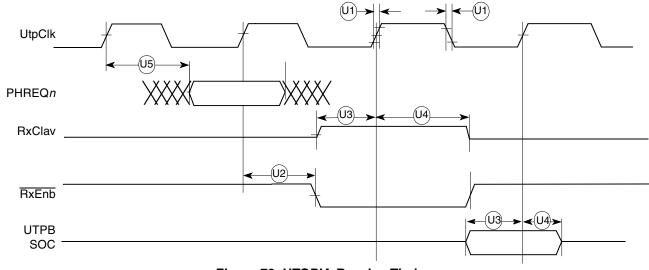
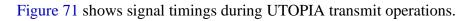


Figure 70. UTOPIA Receive Timing



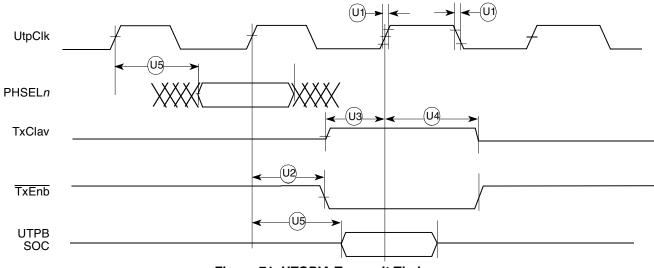


Figure 71. UTOPIA Transmit Timing

This section provides the AC electrical specifications for the Fast Ethernet controller (FEC). Note that the timing specifications for the MII signals are independent of system clock frequency (part speed designation). Also, MII signals use TTL signal levels compatible with devices operating at either 5.0 V or 3.3 V.

13.1 MII Receive Signal Timing (MII_RXD[3:0], MII_RX_DV, MII_RX_ER, MII_RX_CLK)

The receiver functions correctly up to a MII_RX_CLK maximum frequency of 25 MHz + 1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_RX_CLK frequency -1%.

Table 29 provides information on the MII receive signal timing.

Num	Characteristic	Min	Max	Unit
M1	MII_RXD[3:0], MII_RX_DV, MII_RX_ER to MII_RX_CLK setup	5	—	ns
M2	MII_RX_CLK to MII_RXD[3:0], MII_RX_DV, MII_RX_ER hold	5	—	ns
М3	MII_RX_CLK pulse width high	35%	65%	MII_RX_CLK period
M4	MII_RX_CLK pulse width low	35%	65%	MII_RX_CLK period

Table 29. MII Receive Signal Timing

Figure 72 shows MII receive signal timing.

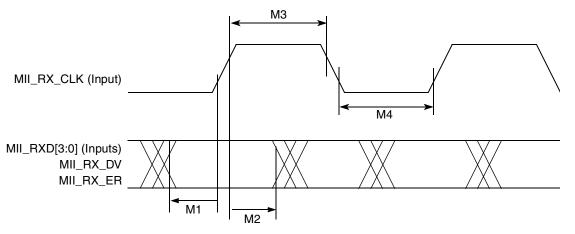


Figure 72. MII Receive Signal Timing Diagram

13.2 MII Transmit Signal Timing (MII_TXD[3:0], MII_TX_EN, MII_TX_ER, MII_TX_CLK)

The transmitter functions correctly up to a MII_TX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_TX_CLK frequency -1%.

Table 30 provides information on the MII transmit signal timing.

Table 30.	MII	Transmit	Signal	Timing
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Num	Characteristic	Min	Мах	Unit
M5	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER invalid	5	_	ns
M6	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER valid	—	25	
M7	MII_TX_CLK pulse width high	35	65%	MII_TX_CLK period
M8	MII_TX_CLK pulse width low	35%	65%	MII_TX_CLK period

Figure 73 shows the MII transmit signal timing diagram.

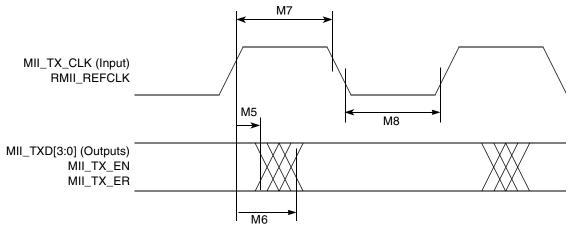


Figure 73. MII Transmit Signal Timing Diagram

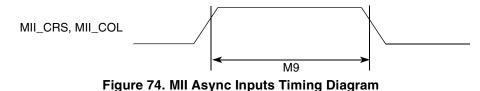
13.3 MII Async Inputs Signal Timing (MII_CRS, MII_COL)

Table 31 provides information on the MII async inputs signal timing.

Table 31. MII Async Inputs Signal Timing

Num	Characteristic	Min	Max	Unit
M9	MII_CRS, MII_COL minimum pulse width	1.5		MII_TX_CLK period

Figure 74 shows the MII asynchronous inputs signal timing diagram.



13.4 MII Serial Management Channel Timing (MII_MDIO, MII_MDC)

Table 32 provides information on the MII serial management channel signal timing. The FEC functions correctly with a maximum MDC frequency in excess of 2.5 MHz. The exact upper bound is under investigation.

Num	Characteristic	Min	Мах	Unit
M10	MII_MDC falling edge to MII_MDIO output invalid (minimum propagation delay)	0	—	ns
M11	MII_MDC falling edge to MII_MDIO output valid (max prop delay)	_	25	ns
M12	MII_MDIO (input) to MII_MDC rising edge setup	10	—	ns
M13	MII_MDIO (input) to MII_MDC rising edge hold	0	—	ns
M14	MII_MDC pulse width high	40%	60%	MII_MDC period
M15	MII_MDC pulse width low	40%	60%	MII_MDC period

Table 32. MII Serial Management Channel Timing

Mechanical Data and Ordering Information

Figure 75 shows the MII serial management channel timing diagram.

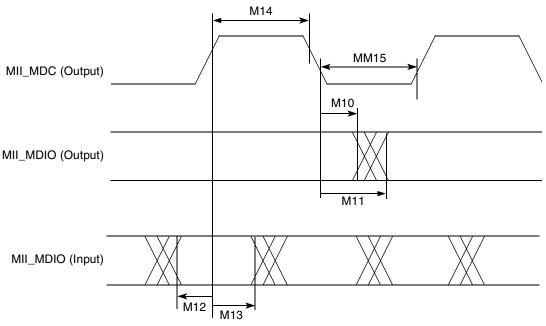


Figure 75. MII Serial Management Channel Timing Diagram

14 Mechanical Data and Ordering Information

14.1 Ordering Information

Table 33 provides information on the MPC860 Revision D.4 derivative devices.

Device	Number of SCCs ¹	Ethernet Support ² (Mbps)	Multichannel HDLC Support	ATM Support
MPC855T	1	10/100	Yes	Yes
MPC860DE	2	10	N/A	N/A
MPC860DT		10/100	Yes	Yes
MPC860DP		10/100	Yes	Yes
MPC860EN	4	10	N/A	N/A
MPC860SR		10	Yes	Yes
MPC860T		10/100	Yes	Yes
MPC860P		10/100	Yes	Yes

Table 33. MPC860 Family Revision D.4 Derivatives

¹ Serial communications controller (SCC)

² Up to 4 channels at 40 MHz or 2 channels at 25 MHz

Table 34 identifies the packages and operating frequencies available for the MPC860.

Package Type	Freq. (MHz) / Temp. (Tj)	Package	Order Number
Ball grid array ZP suffix—leaded ZQ suffix—leaded VR suffix—lead-free	50 0° to 95°C	ZP/ZQ ¹	MPC855TZQ50D4 MPC860DEZQ50D4 MPC860DTZQ50D4 MPC860ENZQ50D4 MPC860SRZQ50D4 MPC860TZQ50D4 MPC860DPZQ50D4 MPC860PZQ50D4
		Tape and Reel	MPC855TZQ50D4R2 MPC860DEZQ50D4R2 MPC860ENZQ50D4R2 MPC860SRZQ50D4R2 MPC860TZQ50D4R2 MPC860TZQ50D4R2 MPC860ENCVR50D4R2 MPC855TVR50D4R2 MPC860ENVR50D4R2 MPC860SRVR50D4R2 MPC860TVR50D4R2
		VR	MPC855TCVR50D4 MPC855TVR50D4 MPC860DEVR50D4 MPC860DPVR50D4 MPC860DTVR50D4 MPC860ENVR50D4 MPC860PVR50D4 MPC860SRVR50D4 MPC860TVR50D4
	66 0° to 95°C	ZP/ZQ ¹	MPC855TZQ66D4 MPC860DEZQ66D4 MPC860DTZQ66D4 MPC860ENZQ66D4 MPC860SRZQ66D4 MPC860TZQ66D4 MPC860DPZQ66D4 MPC860PZQ66D4
		Tape and Reel	MPC860SRZQ66D4R2 MPC860PZQ66D4R2
		VR	MPC855TCVR66D4 MPC855TVR66D4 MPC860DEVR66D4 MPC860DPVR66D4 MPC860DTVR66D4 MPC860ENVR66D4 MPC860PVR66D4 MPC860SRVR66D4 MPC860TVR66D4

Table 34. MPC860 Family Package/Frequency Availability

Mechanical Data and Ordering Information

Package Type	Freq. (MHz) / Temp. (Tj)	Package	Order Number
Ball grid array <i>(continued)</i> ZP suffix—leaded ZQ suffix—leaded VR suffix—lead-free	80 0° to 95°C	ZP/ZQ ¹	MPC855TZQ80D4 MPC860DEZQ80D4 MPC860DTZQ80D4 MPC860ENZQ80D4 MPC860SRZQ80D4 MPC860TZQ80D4 MPC860DPZQ80D4 MPC860PZQ80D4
		Tape and Reel	MPC860PZQ80D4R2 MPC860PVR80D4R2
		VR	MPC855TVR80D4 MPC860DEVR80D4 MPC860DPVR80D4 MPC860ENVR80D4 MPC860PVR80D4 MPC860SRVR80D4 MPC860TVR80D4
Ball grid array (CZP suffix) CZP suffix—leaded CZQ suffix—leaded CVR suffix—lead-free	50 –40° to 95°C	ZP/ZQ ¹	MPC855TCZQ50D4 MPC860DECZQ50D4 MPC860DTCZQ50D4 MPC860ENCZQ50D4 MPC860SRCZQ50D4 MPC860TCZQ50D4 MPC860DPCZQ50D4 MPC860PCZQ50D4
		Tape and Reel	MPC855TCZQ50D4R2 MC860ENCVR50D4R2
		CVR	MPC860DECVR50D4 MPC860DTCVR50D4 MPC860ENCVR50D4 MPC860PCVR50D4 MPC860SRCVR50D4 MPC860TCVR50D4
	66 −40° to 95°C	ZP/ZQ ¹	MPC855TCZQ66D4 MPC860ENCZQ66D4 MPC860SRCZQ66D4 MPC860TCZQ66D4 MPC860DPCZQ66D4 MPC860PCZQ66D4
		CVR	MPC860DTCVR66D4 MPC860ENCVR66D4 MPC860PCVR66D4 MPC860SRCVR66D4 MPC860TCVR66D4

Table 34. MPC860 Family Package/Frequency Availability (continued)

¹ The ZP package is no longer recommended for use. The ZQ package replaces the ZP package.

14.2 Pin Assignments

Figure 76 shows the top view pinout of the PBGA package. For additional information, see the MPC860 PowerQUICC User's Manual, or the MPC855T User's Manual.

/																			
	O PD10	O PD8	O PD3) D0	O D4	O D1	() D2) D3	() D5		O D6	() D7) D29	O DP2				w
O PD14	O PD13	O PD9	O PD6	⊖ M_Tx_I		O D13) D27	() D10	() D14	() D18) D20	() D24	() D28	O DP1	O DP3	O DP0) N/C \		V I
O PA0	O PB14	O PD15	O PD4	O PD5	O IRQ1	() D8	() D23	() D11	() D16	() D19	() D21) D26) D30	O IPA5) IPA4	O IPA2	O N/C	O VSSSYN	U
O PA1	O PC5	O PC4	O PD11	O PD7) H D12	O D17	O D9) D15) D22	O D25	O D31	O IPA6		O IPA1	O IPA7	O XFC		Т
O PC6	0 PA2	O PB15	O PD12	\bigcirc		0	0	0	0	0	\bigcirc	0	0						R VR
O PA4	O PB17	O PA3		\bigcirc	$(\bigcirc$	O GND	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc) GND	\bigcirc				O T XTAL	Ρ
O PB19) PA5	O PB18	〇 PB16	\bigcirc	\bigcirc	0	\bigcirc	0					Ν						
O PA7	O PC8) PA6	O PC7	\bigcirc	\bigcirc	0	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	0	0		BADDR28	BADD	O R29 VDD	M L
O PB22	2 PC9	() PA8	О РВ20	\bigcirc	\bigcirc	0	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	0	\bigcirc	() OP0		O OP1		L
O PC1) PA9	О РВ23	〇 PB21	\bigcirc	0	0	\bigcirc	\bigcirc	O GND	\bigcirc	\bigcirc	\bigcirc	0	0		0 30 IPB6			к
O PC1	O I PB24) PA10	О РВ25	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	0	0	O IPB5	O IPB1	O IPB2	O	J
			О тск	\bigcirc	0	\bigcirc	0	O M_COL			O IPB7	н							
	О Г тмs) TDO	O PA11	\bigcirc	\bigcirc) GND	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc) GND	0			O IPB4	O IPB3	G
O PB20	O PC12	〇 PA12		\bigcirc		0	0	0	0	0	0	0	0			⊖ ⊤s			F
O PB2	O PC13) PA13	O PB29	\bigcirc	0	0	0	0	0	0	0	0	0	0	\bigcirc CS3	⊖ Bī	\bigcirc BG		Е
O PB28	O 8 PC14) PA14	O PC15	() A8	O N/C	O N/C	() A15	() A19	() A25	() A18			⊖ N/C		\bigcirc CS2				D
O PB30	O PA15) PB31	() A3	() A9	() A12	() A16	() A20	() A24	() A26	O TSIZ1					\bigcirc CS7				С
() A0	() A1	() A4	() A6	() A10	() A13	() A17	() A21	() A23	() A22	O TSIZO			$\bigcirc \\ \overline{\text{WE2}}$		\bigcirc CS5		$\bigcirc \overline{\rm WR}$		В
	() A2	() A5	() A7	() A11	() A14	() A27	() A29	() A30	() A28) A31			$\bigcirc \\ \overline{WE1}$		\bigcirc CS4		$\frac{\bigcirc}{CS1}$		A
19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	١

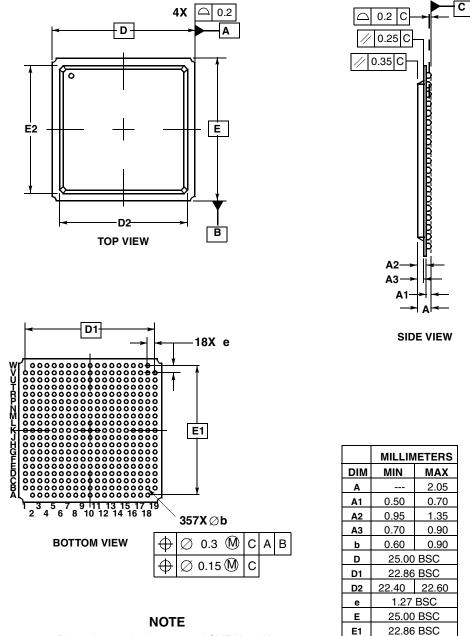
NOTE: This is the top view of the device.

Figure 76. Pinout of the PBGA Package

Mechanical Data and Ordering Information

14.3 Mechanical Dimensions of the PBGA Package

Figure 77 shows the mechanical dimensions of the ZP PBGA package.



- 1. Dimensions and tolerance per ASME Y14.5M, 1994.
- 2. Dimensions in millimeters.
- 3. Dimension b is the maximum solder ball diameter measured parallel to data C.

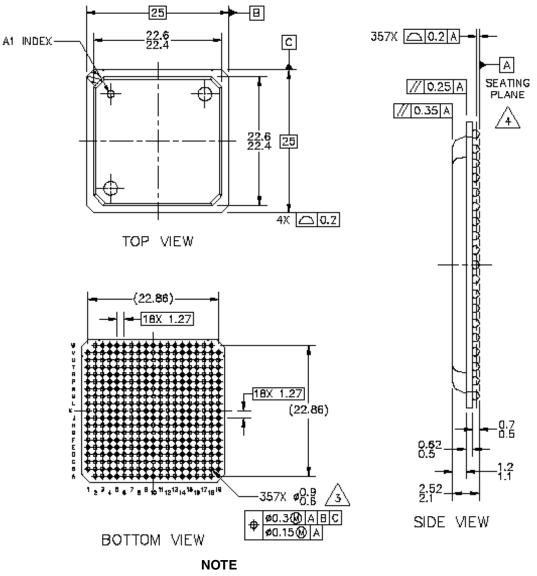


22.40

E2

22.60

Figure 78 shows the mechanical dimensions of the ZQ PBGA package.



- 1. All Dimensions in millimeters.
- 2. Dimensions and tolerance per ASME Y14.5M, 1994.
- 3. Maximum Solder Ball Diameter measured parallel to Datum A.
- 4. Datum A, the seating plane, is defined by the spherical crowns of the solder balls.

Figure 78. Mechanical Dimensions and Bottom Surface Nomenclature of the ZQ PBGA Package

Document Revision History

15 Document Revision History

Table 35 lists significant changes between revisions of this hardware specification.

Revision	Date	Changes
9	10/2011	Updated orderable part numbers in Table 34, "MPC860 Family Package/Frequency Availability."
8	08/2007	 Updated template. On page 1, added a second paragraph. After Table 2, inserted a new figure showing the undershoot/overshoot voltage (Figure 1) and renumbered the rest of the figures. In Figure 3, changed all reference voltage measurement points from 0.2 and 0.8 V to 50% level. In Table 16, changed num 46 description to read, "TA assertion to rising edge" In Figure 46, changed TA to reflect the rising edge of the clock.
7.0	9/2004	 Added a tablefootnote to Table 6 DC Electrical Specifications about meeting the VIL Max of the I2C Standard Replaced the thermal characteristics in Table 4 by the ZQ package Add the new parts to the Ordering and Availability Chart in Table 34 Added the mechanical spec of the ZQ package in Figure 78 Removed all of the old revisions from Table 5
6.3	9/2003	•Added Section 11.2 on the Port C interrupt pins •Nontechnical reformatting
6.2	8/2003	 Changed B28a through B28d and B29d to show that TRLX can be 0 or 1 Changed reference documentation to reflect the Rev 2 MPC860 PowerQUICC Family Users Manual Nontechnical reformatting
6.1	11/2002	 Corrected UTOPIA RXenb* and TXenb* timing values Changed incorrect usage of Vcc to Vdd Corrected dual port RAM to 8 Kbytes
6	10/2002	Added the MPC855T. Corrected Figure 26 on page -36.
5.1	11/2001	Revised template format, removed references to MAC functionality, changed Table 7 B23 max value @ 66 MHz from 2ns to 8ns, added this revision history table

Table 35. Document Revision History

Document Revision History

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